

Superconducting and Normal State Properties of APd₂As₂ ($A = \text{Ca, Sr, Ba}$) Single Crystals

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The synthesis and crystallography, magnetic susceptibility χ , magnetization M , specific heat C_p , in-plane electrical resistivity ρ and in-plane magnetic penetration depth measurements are reported for single crystals of APd₂As₂ ($A = \text{Ca, Sr, Ba}$) versus temperature T and magnetic field H . The crystals were grown using PdAs self-flux. CaPd₂As₂ and SrPd₂As₂ crystallize in a collapsed body-centered tetragonal ThCr₂Si₂-type structure ($I4/mmm$), whereas BaPd₂As₂ crystallizes in the primitive tetragonal CeMg₂Si₂-type structure ($P4/mmm$), in agreement with literature data. The $\rho(T)$ data exhibit metallic behavior for all three compounds. Bulk superconductivity is reported for CaPd₂As₂ and SrPd₂As₂ below $T_c = 1.27$ and 0.92 K, respectively, whereas only a trace of superconductivity is found in BaPd₂As₂. No other phase transitions were observed. The $\chi(T)$ and $M(H)$ data reveal anisotropic diamagnetism in the normal state, with $\chi_c > \chi_{ab}$ for CaPd₂As₂ and BaPd₂As₂, and $\chi_c < \chi_{ab}$ for SrPd₂As₂. The normal and superconducting state data indicate that CaPd₂As₂ and SrPd₂As₂ are conventional type-II nodeless s -wave electron-phonon superconductors. The electronic superconducting-state heat capacity data for CaPd₂As₂, which has an extremely sharp heat capacity jump at T_c , are analyzed using our recent elaboration of the α -model of the BCS theory of superconductivity, which indicates that the s -wave gap in this compound is anisotropic in momentum space.

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I. INTRODUCTION

The observation of high-temperature superconductivity (SC) with transition temperatures $T_c \lesssim 38$ K in doped 122-type iron arsenides such as in $A_{1-x}K_xFe_2As_2$ ($A = \text{Ba, Sr, Ca and Eu}$) compounds has stimulated great interest in these materials.^{1–15} The parent compounds AFe₂As₂ with $A = \text{Ca, Sr, and Ba}$ are itinerant antiferromagnetic (AF) semimetals that undergo a structural distortion from a tetragonal structure to an orthorhombic one on cooling below room temperature. The structural transition precedes a long-range AF itinerant spin density wave (SDW) transition. Superconductivity in these compounds emerges upon suppression of the SDW transition that can be achieved either by partial chemical substitutions at either the A , Fe or As sites or by application of external pressure.¹¹ The same phenomenology is found in the high- T_c cuprates where the long-range AF order must be largely suppressed by doping prior to the emergence of superconductivity, but strong dynamic AF spin fluctuations must still be present. Thus, the iron arsenides and the high- T_c cuprates have the same generic phase diagram for the emergence of superconductivity, even though the cuprate parent compounds are AF insulators rather than SDW semimetals.^{11–13,16–18}

The partial substitutions at the Fe-site in AFe₂As₂ by transition metals M in Ba(Fe_{1-x} M_x)₂As₂ with $M = \text{Cr, Mn, Co, Ni, Cu, Ru, Rh, and Pd}$ have recently been studied both theoretically and experimentally from the perspective of the degree of charge doping because of the changes in the magnetic and SC properties caused by such substitutions.^{6,12,19–39} The substitutions for the Fe atoms by the 3d elements Co and Ni

and the 4d elements Rh and Pd which have higher number of 3d electrons than that of Fe are found to induce superconductivity.^{6,21,22,27,28} However, no superconductivity is induced by Mn or Cr substitutions having a lower number of 3d electrons.^{23–26} On the other hand isoelectronic substitution of Fe by the 4d transition metal Ru is also found to induce the superconductivity.^{29,30} The common feature in the SC materials is that the long-range SDW order in the parent compounds must be largely suppressed before SC occurs as noted above, where, in addition, the AF spin fluctuations are still strong. The latter fact suggests an unconventional magnetic mechanism for the SC in the FeAs-based materials. The extent and effects of electron and hole doping by such substitutions are still being debated.^{12,31,37,39–41}

While the effect of partial substitutions of Fe by transition metals have been investigated extensively, the physical properties of the end-point compounds AM_2As_2 of the $A(\text{Fe}_{1-x}M_x)_2\text{As}_2$ series are often not known in detail. Recently we reported crystallography and physical property studies of the end-point compounds SrCu₂As₂ and CaCu_{1.7}As₂ for $M = \text{Cu}$ which are sp -band metals.^{40,41} These compounds form in a collapsed tetragonal (cT) structure in which the formal oxidation state of As is As⁻² \equiv [As–As]⁻⁴/2 due to the interlayer As–As bonding in the cT phase. Thus with the formal oxidation states of Sr and Ca taken to be +2, the Cu atoms in these cT compounds are then Cu⁺¹ with a nonmagnetic 3d¹⁰ configuration as observed^{40,41} and also as previously predicted from electronic structure calculations for SrCu₂As₂ by Singh.⁴² Thus, extrapolating from high to low Cu concentrations, the electron or hole doping effect resulting from substitution of $M = \text{Cu}$ for Fe in $A(\text{Fe}_{1-x}M_x)_2\text{As}_2$

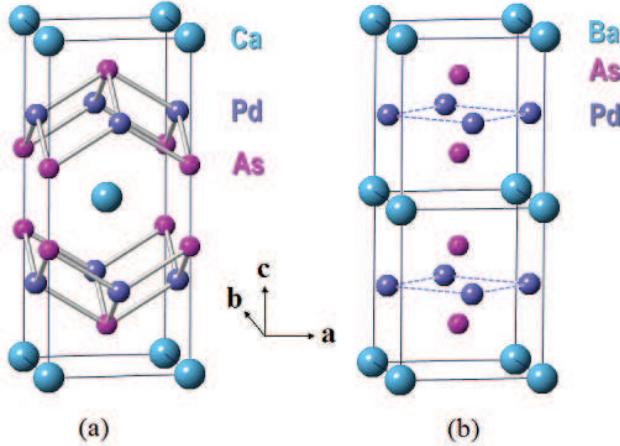


FIG. 1: (Color online) (a) A unit cell of ThCr₂Si₂-type body-centered tetragonal crystal structure (*I*4/*mmm*) of CaPd₂As₂ and SrPd₂As₂. (b) Two unit cells, stacked along the *c*-axis, of the CeMg₂Si₂-type primitive tetragonal crystal structure (*P*4/*mmm*) of BaPd₂As₂.

compounds is ambiguous and interesting.^{12,39,40}

To provide insight into the *T*-*x* phase diagrams of $A(\text{Fe}_{1-x}\text{M}_x)_2\text{As}_2$ systems with $M = \text{Pd}$, we report here our investigations of the crystallography and physical properties of single crystals of the three (Ca,Sr,Ba)Pd₂As₂ end-point compounds. CaPd₂As₂ and SrPd₂As₂ are reported to form in the body-centered tetragonal ThCr₂Si₂-type structure (space group *I*4/*mmm*) and BaPd₂As₂ in the primitive tetragonal CeMg₂Si₂-type structure (space group *P*4/*mmm*),^{43,44} as shown in Fig. 1 for CaPd₂As₂ and BaPd₂As₂. Both structures contain similar Pd square-lattices. However, while the Ca atoms in CaPd₂As₂ form a body-centered tetragonal sublattice, in the BaPd₂As₂ structure they form a primitive tetragonal sublattice. Furthermore, the fourfold coordination of Pd by As is tetrahedral in CaPd₂As₂ but is planar rectangular in BaPd₂As₂. The BaPd₂As₂ structure can be derived from that of CaPd₂As₂ by a $[\frac{1}{2}, \frac{1}{2}, 0]$ translation of the central As-Ca-As layer. Superconductivity was recently reported below $T_c = 3.0$ K in the similar compound SrPd₂Ge₂ with the ThCr₂Si₂-type structure.⁴⁵

In this paper we report crystallographic investigations of crushed single crystal powders and physical property measurements of single crystals of the three (Ca,Sr,Ba)Pd₂As₂ compounds using magnetic susceptibility χ , isothermal magnetization M , specific heat C_p , and *ab*-plane electrical resistivity ρ measurements as a function of temperature T and applied magnetic field H . The published structures of these compounds are confirmed. The $\rho(T)$, $\chi(T)$ and $C_p(T)$ data demonstrate that all three compounds are *sp*-band metals. The $\chi(T)$ data indicate anisotropic diamagnetic behavior in all three compounds with $\chi_c > \chi_{ab}$ for CaPd₂As₂ and BaPd₂As₂ and $\chi_c < \chi_{ab}$ for SrPd₂As₂. Bulk superconducting transitions at $T_c = 1.27(3)$ K for CaPd₂As₂

and $T_c = 0.92(5)$ K for SrPd₂As₂ are also reported together with other superconducting-state properties derived from the above measurements as well as from magnetic penetration depth measurements. We analyzed the superconducting-state electronic entropy and heat capacity data using our recent elaboration of the α -model of the BCS theory of superconductivity.⁴⁶ The data indicate that CaPd₂As₂ and SrPd₂As₂ are both conventional nodeless type-II electron-phonon superconductors, but with anisotropic *s*-wave gaps. Filamentary superconductivity was also detected below 2.0 K in BaPd₂As₂.

The experimental details are described in Sec. II. The crystallographic studies of CaPd₂As₂, SrPd₂As₂ and BaPd₂As₂ are presented in Sec. III and the physical properties in Secs. IV, V, and VI, respectively. Our measurements of the superconducting magnetic penetration depths versus temperature for CaPd₂As₂ and SrPd₂As₂ are presented in Sec. VII. A summary of the experimental results and analyses and the conclusions are given in Sec. VIII.

II. EXPERIMENTAL DETAILS

Single crystals of APd_2As_2 ($A = \text{Ba, Ca, Sr}$) were grown using PdAs flux. The starting materials were high-purity elemental Ca (99.98%), Pd (99.998%) and As (99.99999%) from Alfa Aesar and Sr (99.95%) and Ba (99.99%) from Sigma Aldrich. The Ca, Sr or Ba and pre-reacted PdAs flux taken in a 1:4 molar ratio were placed in alumina crucibles and sealed inside evacuated fused silica tubes. The sealed samples were heated to 1100 °C at a rate of 60–80 °C/h and held there for 12 h. After cooling at a rate of 2.5 °C/h to 800 °C, shiny plate-like crystals of typical size $2 \times 1.5 \times 0.4$ mm³ were separated by decanting the flux with a centrifuge at that temperature.

The phase purity and the chemical composition of the CaPd₂As₂, SrPd₂As₂ and BaPd₂As₂ crystals were measured using a JEOL scanning electron microscope (SEM) equipped with an energy-dispersive x-ray analyzer (EDX). High-resolution SEM images demonstrated that the crystals were single-phase. The EDX analyses of two or three single crystals of each compound were consistent with the ideal 1 : 2 : 2 stoichiometry. The crystal structures of the samples were determined by Rietveld refinements of powder x-ray diffraction (XRD) data for crushed single crystals collected on a Rigaku Geigerflex x-ray diffractometer using Cu $K\alpha$ radiation. The Rietveld refinements were carried out using the FullProf software⁴⁷ which also confirmed the single-phase nature of the crystals.

The magnetization measurements were performed using a Quantum Design, Inc., superconducting quantum interference device magnetic properties measurement system (MPMS). We use Gaussian cgs units for the magnetic results and discussion, where the unit of magnetic field H is the Oe = G, but we also use the Tesla, with 1 T $\equiv 10^4$ Oe, as a unit of convenience (the magnetic mo-

ment output by the MPMS software is in Gaussian cgs units where $1 \text{ emu} = 1 \text{ G cm}^3$).¹¹ In order to obtain the magnetic moment of the crystals in a particular field H we subtracted the pre-calibrated magnetic moment of the sample holder (quartz rod/plastic piece and GE varnish that were used to mount the sample for MPMS measurements) in the same H . Due to the small magnitudes of the magnetic moments of the small crystals and the uncertainty in the magnetic moment of sample holder, the accuracy of the $M(H, T)$ and $\chi(T)$ data of the samples reported here is of order 10%.

The heat capacity measurements were carried out using the relaxation method in a Quantum Design, Inc., physical properties measurement system (PPMS). Temperatures down to 0.45 K were obtained using a ^3He attachment to the PPMS. The ab -plane $\rho(T)$ measurements were performed by the standard four-probe ac technique using the ac transport option of the PPMS. The electrical leads were 25 μm diameter platinum wires attached to the crystals with EPO-TEK P1011 silver epoxy cured at 110 °C for one hour. The accuracy of ρ is of order 10% due to uncertainties in the geometric factor.

The temperature variation of the magnetic penetration depth λ_{eff} was measured using a tunnel diode resonator (TDR) technique operating at about 15 MHz. The resonator consists of an LC tank circuit with a single-layer coil of inductance $L \sim 1 \mu\text{H}$, a capacitor with capacitance $C \sim 100 \text{ pF}$ and a tunnel diode that is biased to the region of negative differential resistance, thus compensating the losses in the circuit. The circuit, therefore, self-oscillates at a frequency $f = (2\pi\sqrt{LC})^{-1}$. When a sample with magnetic susceptibility χ is inserted into the coil, the total inductance changes and the resonant frequency shifts accordingly by an amount which is proportional to χ . The temperature dependence of the resonance frequency shift $\Delta f(T)$ induced by changes in the sample's magnetic response is related to the magnetic susceptibility χ and hence $\lambda_{\text{eff}}(T)$ by^{48–50}

$$\begin{aligned} \Delta f(T) &= -4\pi\chi(T)G & (1) \\ &\approx -G \left\{ 1 - \frac{\lambda_{\text{eff}}(T)}{L_{\text{eff}}} \tanh \left[\frac{L_{\text{eff}}}{\lambda_{\text{eff}}(T)} \right] \right\}, \end{aligned}$$

where G is a sample- and coil-dependent calibration constant and L_{eff} is the effective sample dimension.⁴⁸ The value of G is determined experimentally by pulling the sample out of the coil *in situ* and measuring the total associated frequency shift, Δf_0 , so that $\Delta\lambda_{\text{eff}}(T) = L_{\text{eff}} \delta f(T)/\Delta f_0$ where $\Delta\lambda_{\text{eff}}(T) = \lambda_{\text{eff}}(T) - \lambda_{\text{eff}}(T_{\text{min}})$, $\delta f(T) = f(T) - f(T_{\text{min}})$ and T_{min} is the minimum temperature of the measurement.⁴⁸ Another way to determine G is by matching the temperature dependence of the skin depth, $d(T)$, obtained from the resonator response in the normal state to the measured resistivity, $\rho(T)$, by using the relation $d(T) = (c/2\pi)\sqrt{\rho(T)/f}$.⁵¹ The ac magnetic field was applied along the c -axis of single crystals of CaPd_2As_2 and SrPd_2As_2 , so the reported

penetration depths are the respective values in the ab -plane.

III. CRYSTALLOGRAPHY

The room temperature powder XRD patterns for crushed single crystals of CaPd_2As_2 , SrPd_2As_2 and BaPd_2As_2 are shown in Figs. 2(a), 2(b) and 2(c), respectively. The weak unindexed peaks marked with stars for BaPd_2As_2 arise from the small amount of flux attached to the surface of the crystals prior to crushing them for the measurements. The Rietveld refinements confirmed the reported ThCr_2Si_2 -type body-centered tetragonal structure (space group $I4/mmm$) of CaPd_2As_2 and SrPd_2As_2 and the CeMg_2Si_2 -type primitive tetragonal structure (space group $P4/mmm$) of BaPd_2As_2 .^{43,44}

The refinement profiles for these structural models are shown in Fig. 2. During the final refinements, the thermal parameters B were set to $B = 0$ and the occupancies of the respective atomic sites were fixed to unity, since there were no improvements in the quality of fits or significant changes in the lattice parameters or in the As c -axis position parameter z_{As} upon making small changes in B and in the occupancies. The crystallographic and refinement parameters are listed in Tables I and II. For comparison the lattice parameters and z_{As} values from the literature are also listed in Table I, where good agreement is found.

The c/a ratio and the interlayer As–As distance $d_{\text{As–As}} = (1 - 2z_{\text{As}})c$ for $(\text{Ca},\text{Sr})\text{Pd}_2\text{As}_2$ and $2z_{\text{As}}c$ for BaPd_2As_2 are listed in Table I, where a “layer” is defined as an As–Pd–As slab in Fig. 1. The values of $d_{\text{As–As}}$ for CaPd_2As_2 and SrPd_2As_2 are close to the covalent single-bond distance of 2.38 Å for As,⁵² indicating that these two compounds have cT structures.⁴⁰ Therefore, as discussed in Sec. I, the formal oxidation state of Pd in these $(\text{Ca},\text{Sr})\text{Pd}_2\text{As}_2$ compounds is Pd^{+1} , which is the same formal oxidation state as for Cu in ThCr_2Si_2 -type SrCu_2As_2 .⁴⁰

IV. PHYSICAL PROPERTIES OF CaPd_2As_2 CRYSTALS

A. Electrical Resistivity

The in-plane ρ of CaPd_2As_2 versus T is shown for crystal #1 at $H = 0$ in Fig. 3(a) and for crystal #2 under various H in Fig. 3(b). A sharp zero-field superconducting transition is observed in Fig. 3(b) at $T_c = 1.28(3)$ K that is suppressed by $H = 0.14$ T to below 0.45 K. For crystal #1 the superconducting onset is also at 1.8 K as shown in the inset of Fig. 3(a). A broad superconducting transition was seen in another crystal (#3) with an onset at 1.8 K and zero resistance at 1.3 K (not shown). Interestingly the $\rho(T)$ of crystal #2 in Fig. 3(b) exhibits an upturn and peak before the resistivity drops due to superconductivity which is suppressed by a field $H \geq 0.08$ T.

TABLE I: Crystallographic and Rietveld refinement parameters obtained from powder XRD data for crushed APd_2As_2 ($A = Ba, Ca, Sr$) crystals. Error bars for the last digit of a quantity are given in parentheses and literature references are given in square brackets.

| | CaPd ₂ As ₂ | SrPd ₂ As ₂ | BaPd ₂ As ₂ |
|--|---|---|---|
| Structure | ThCr ₂ Si ₂ -type body-centered tetragonal | ThCr ₂ Si ₂ -type body-centered tetragonal | CeMg ₂ Si ₂ -type primitive tetragonal |
| Space group | $I\bar{4}/mmm$ | $I\bar{4}/mmm$ | $P\bar{4}/mmm$ |
| Formula units/unit cell (Z) | 2 | 2 | 1 |
| Lattice parameters | | | |
| a (Å) | 4.2824(2) 4.299(1) [43] 4.283(1) [44] | 4.3759(1) 4.383(1) [43] 4.380(2) [44] | 4.3438(2) 4.346(1) [43] |
| c (Å) | 10.0880(4) 10.102(2) [43] 10.093(1) [44] | 10.1671(3) 10.179(2) [43] 10.169(1) [44] | 5.7536(2) 5.758(1) [43] |
| c/a | 2.3557(6) | 2.3234(4) | 1.3246(4) |
| V_{cell} (Å ³) | 185.01(1) | 194.69(1) | 108.56(1) |
| As c -axis coordinate z_{As} | 0.3763(3) 0.3796(2) [43] | 0.3768(1) 0.3766(2) [43] 0.3768(1) [44] | 0.2705(4) 0.2700(8) [43] |
| As–As interlayer bond distance d_{As-As} (Å) | 2.496(7) | 2.505(2) | 3.113(4) |
| Theoretical density (g/cm ³) | 7.230 | 7.682 | 7.648 |
| Molar volume V_M (cm ³ /mol) | 55.71 | 58.62 | 65.38 |
| Refinement quality | | | |
| χ^2 (%) | 11.8 | 3.68 | 8.09 |
| R_p (%) | 12.7 | 5.41 | 7.39 |
| R_{wp} (%) | 18.6 | 7.23 | 11.2 |

TABLE II: Atomic coordinates obtained from the Rietveld refinements of powder XRD data for crushed APd_2As_2 ($A = Ba, Ca, Sr$) crystals.

| Atom | Wyckoff symbol | x | y | z |
|--|----------------|-----|-----|-----------|
| CaPd ₂ As ₂ ($I\bar{4}/mmm$) | | | | |
| Ca | 2a | 0 | 0 | 0 |
| Pd | 4d | 0 | 1/2 | 1/4 |
| As | 4e | 0 | 0 | 0.3763(3) |
| SrPd ₂ As ₂ ($I\bar{4}/mmm$) | | | | |
| Sr | 2a | 0 | 0 | 0 |
| Pd | 4d | 0 | 1/2 | 1/4 |
| As | 4e | 0 | 0 | 0.3768(1) |
| BaPd ₂ As ₂ ($P\bar{4}/mmm$) | | | | |
| Ba | 1a | 0 | 0 | 0 |
| Pd | 2e | 0 | 1/2 | 1/2 |
| As | 2h | 1/2 | 1/2 | 0.2705(4) |

The origin of this $\rho(T)$ peak is not clear. For crystal #1 the residual resistivity at 2 K before entering the superconducting state is $\rho_0 = 43 \mu\Omega \text{ cm}$ and the residual resistivity ratio is $\text{RRR} \equiv \rho(300 \text{ K})/\rho(2 \text{ K}) \approx 3$.

In the following we fit the normal-state $\rho(T)$ data by the Bloch-Grüneisen (BG) model which describes the electrical resistivity $\rho_{\text{BG}}(T)$ due to scattering of the charge carriers by longitudinal acoustic lattice vibrations

in the absence of Umklapp scattering, given by^{53,54}

$$\rho_{\text{BG}}(T/\Theta_R) = 4\mathcal{R} \left(\frac{T}{\Theta_R} \right)^5 \int_0^{\Theta_R/T} \frac{x^5}{(e^x - 1)(1 - e^{-x})} dx, \quad (2a)$$

where Θ_R is the Debye temperature obtained from fitting resistivity measurements and \mathcal{R} is a material-dependent prefactor that is independent of T . The experimental $\rho(T)$ data are fitted by

$$\rho(T) = \rho_0 + \rho(\Theta_R)\rho_{\text{BG}}(T/\Theta_R), \quad (2b)$$

where Eq. (2a) yields

$$\rho(T/\Theta_R = 1) = 4\mathcal{R} \int_0^1 \frac{x^5}{(e^x - 1)(1 - e^{-x})} dx \quad (2c) \\ \approx 0.946\,464\mathcal{R}.$$

The integral in Eq. (2c) can be obtained in closed form but the expression is cumbersome.

An excellent fit of the $\rho(T)$ data by Eqs. (2) was obtained using the three independent fitting parameters ρ_0 , $\rho(\Theta_R)$ and Θ_R for $2 \text{ K} \leq T \leq 300 \text{ K}$, as shown by the red curve in Fig. 3(a). The single parameter Θ_R determines the T dependence of the fit. While fitting the $\rho(T)$ data we used the analytic Padé approximant function of T/Θ_R in place of Eq. (2a) as developed in Ref. 54 which accurately describes $\rho_{\text{BG}}(T/\Theta_R)$ and greatly simplifies least-squares fitting of experimental $\rho(T)$ data by

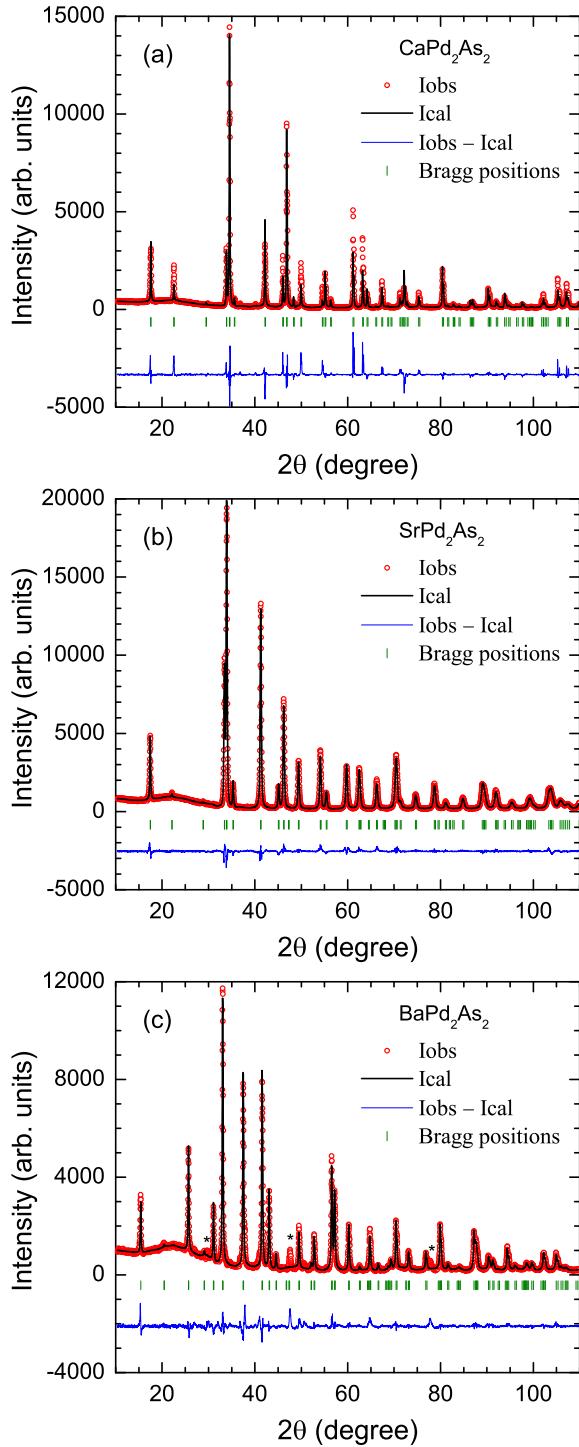


FIG. 2: (Color online) Powder x-ray diffraction patterns of (a) CaPd_2As_2 , (b) SrPd_2As_2 and (c) BaPd_2As_2 recorded at room temperature. The solid lines through the experimental points are the Rietveld refinement profiles calculated [(a) and (b)] for the ThCr_2Si_2 -type body-centered tetragonal structure (space group $I4/mmm$), and (c) for the CeMg_2Si_2 -type primitive tetragonal structure (space group $P4/mmm$). In (a), (b) and (c), the short vertical bars mark the fitted Bragg peak positions. The lowermost curves represent the differences between the experimental and calculated intensities. The unindexed peaks marked with stars correspond to peaks from residual PdAs flux on the surface of the samples.

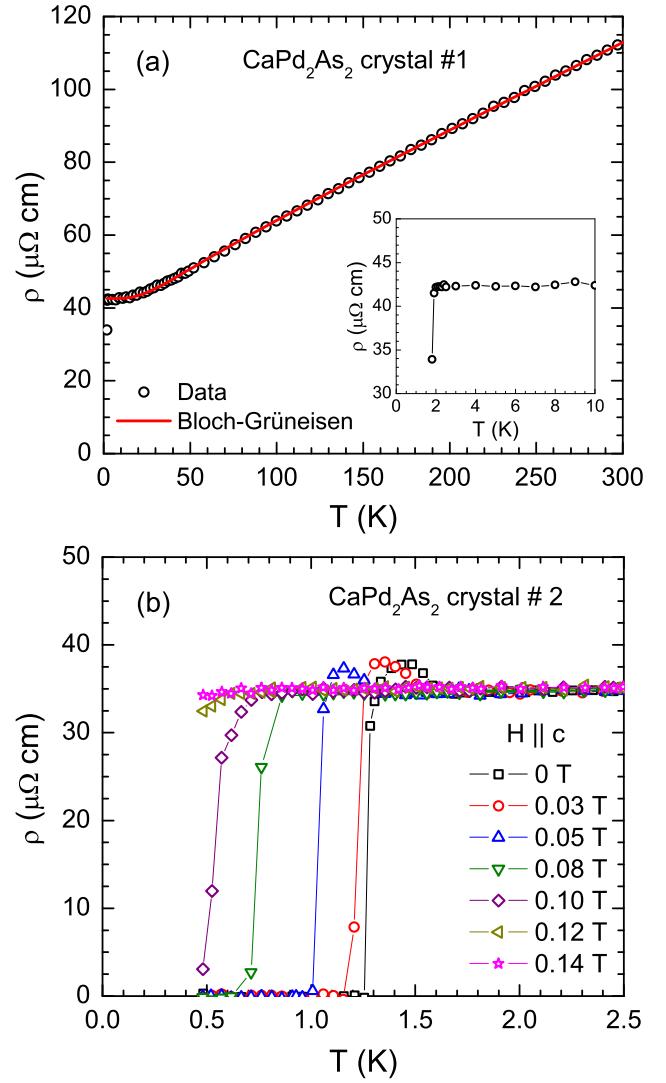


FIG. 3: (Color online) (a) In-plane electrical resistivity ρ of a CaPd_2As_2 crystal #1 versus temperature T measured in applied magnetic field $H = 0$. The red curve is a fit by the Bloch-Grüneisen model in the T range 2–300 K. Inset: Expanded plot of $\rho(T)$ below 10 K to show the onset of superconductivity at 2.0 K. (b) Expanded plot of $\rho(T)$ of CaPd_2As_2 crystal #2 for $0.45 \text{ K} \leq T \leq 2.5 \text{ K}$ showing the superconducting transition for different values of H , as listed, applied along the c -axis.

the BG theory. The fitting parameters are summarized in Table III along with those of the other two compounds discussed below. The \mathcal{R} value is obtained from the fitted value of $\rho(\Theta_R)$ using Eq. (2c).

TABLE III: Parameters derived from Bloch-Grüneisen fits to the resistivities ρ within the ab -plane of the listed single crystals obtained using Eqs. (2). Here ρ_0 is the residual resistivity extrapolated to $T = 0$, Θ_R is the Debye temperature determined from resistivity measurements, $\rho(\Theta_R)$ is the fitted value of ρ at $T = \Theta_R$, and \mathcal{R} is obtained from the fitted value of $\rho(\Theta_R)$ using Eq. (2c). The ρ and \mathcal{R} values do not take into account the systematic error of order 10% arising from uncertainties in the geometric factor required to calculate ρ of a crystal from its measured resistance. The accuracy of Θ_R is not affected by this systematic error since this parameter is determined solely from the T dependence of ρ .

| Compound | ρ_0 ($\mu\Omega$ cm) | Θ_R (K) | $\rho(\Theta_R)$ ($\mu\Omega$ cm) | \mathcal{R} ($\mu\Omega$ cm) |
|-----------------------------------|-------------------------------|-------------------|---------------------------------------|------------------------------------|
| CaPd ₂ As ₂ | 42.60(7) | 135(3) | 30.3(5) | 32.0 |
| SrPd ₂ As ₂ | 7.57(6) | 170(3) | 27.6(5) | 29.2 |
| BaPd ₂ As ₂ | 1.02(1) | 114(1) | 8.84(1) | 9.34 |

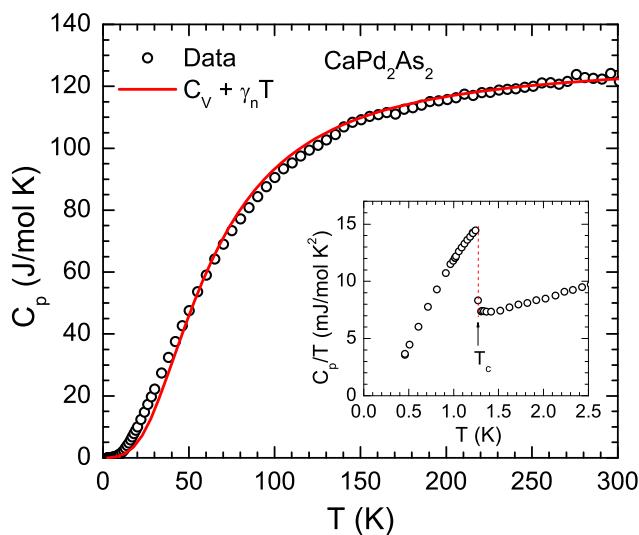


FIG. 4: (Color online) The heat capacity C_p of a CaPd₂As₂ single crystal [crystal #2 of Fig. 3(b)] versus temperature T for $2.5 \text{ K} \leq T \leq 300 \text{ K}$ measured in zero magnetic field. The red solid curve is the fitted sum of the contributions from the Debye lattice heat capacity $C_V^{\text{Debye}}(T)$ and predetermined electronic heat capacity $\gamma_n T$ according to Eq. (5a). Inset: C_p/T vs. T for $0.45 \text{ K} \leq T \leq 2.5 \text{ K}$. The dotted red vertical line indicates the T_c .

B. Heat Capacity

1. Overview of the Superconducting and Normal State Heat Capacity

The $C_p(T)$ of a CaPd₂As₂ crystal is shown in Fig. 4 for $0.45 \text{ K} \leq T \leq 300 \text{ K}$. As shown in the expanded plot of the low- T data in the inset of Fig. 4, a sharp jump is observed in $C_p(T)$ due to the occurrence of superconductivity at $T_c = 1.27(3) \text{ K}$. The $C_p(T)$ data measured under various H are shown in Fig. 5(a). These data show that the T_c decreases with increasing H and is suppressed

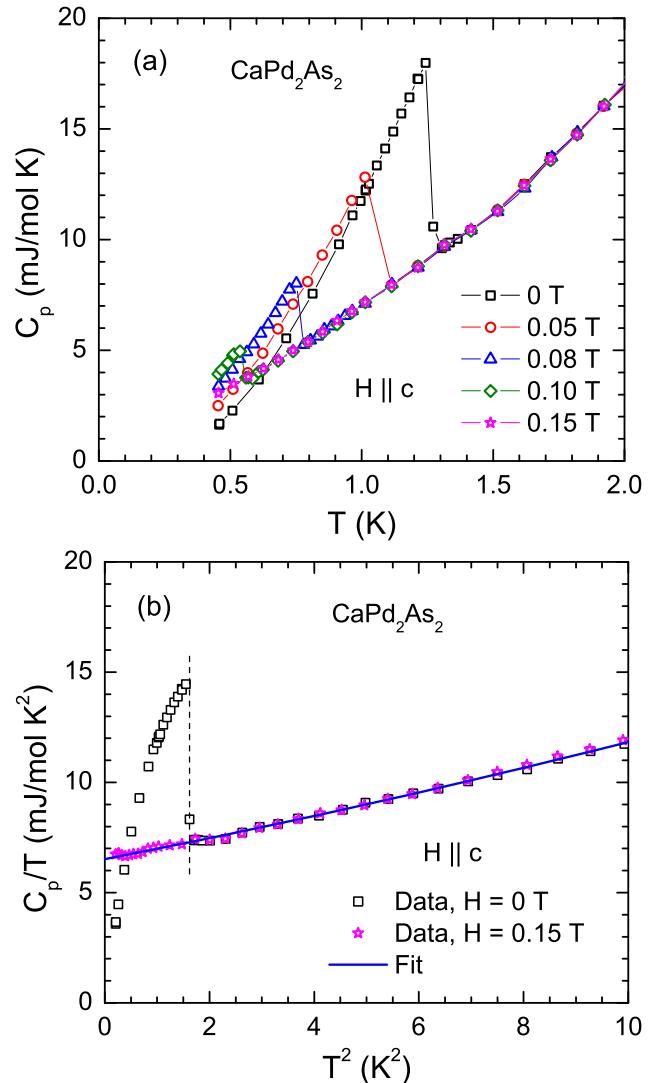


FIG. 5: (Color online) (a) Heat capacity C_p versus temperature T of a CaPd₂As₂ single crystal [crystal #2 of Fig. 3(b)] for $0.45 \text{ K} \leq T \leq 2.0 \text{ K}$ measured in different magnetic fields H applied along the c -axis. (b) C_p/T versus T^2 for $0.45 \text{ K} \leq T \leq 3.2 \text{ K}$ with $H = 0$ and 0.15 T . The blue curve is a fit of the $H = 0.15 \text{ T}$ data for $0.45 \text{ K} \leq T \leq 4.5 \text{ K}$ together with the $H = 0$ data for $1.5 \text{ K} \leq T \leq 4.5 \text{ K}$ by Eq. (3).

to below 0.45 K by $H = 0.15 \text{ T}$.

Plots of C_p/T vs. T^2 for $H = 0$ and 0.15 T are shown in Fig. 5(b). We analyzed the normal-state $C_p(T)$ data at $0.45 \text{ K} \leq T \leq 4.5 \text{ K}$ for $H = 0.15 \text{ T}$ and the data at $1.5 \text{ K} \leq T \leq 4.5 \text{ K}$ for $H = 0$ together according to

$$\frac{C_p(T)}{T} = \gamma_n + \beta T^2 + \delta T^4, \quad (3)$$

where γ_n is the normal state Sommerfeld electronic heat capacity coefficient, β is the Debye T^3 -law lattice heat capacity coefficient and δT^4 is a higher-order lattice contribution. A fit of the normal-state data by

TABLE IV: The linear specific heat coefficients γ_n and the coefficients β and δ of the T^3 and T^5 terms in the low- T heat capacity, respectively, and the density of states at the Fermi energy $\mathcal{D}(E_F)$ for both spin directions for CaPd_2As_2 , SrPd_2As_2 and BaPd_2As_2 single crystals. The Debye temperatures Θ_D obtained at low T and for all T from heat capacity measurements and the Debye temperature Θ_R obtained from fitting electrical resistivity data, respectively, are also listed.

| Compound | γ_n (mJ/mol K ²) | β (mJ/mol K ⁴) | δ ($\mu\text{J/mol K}^6$) | $\mathcal{D}(E_F)$ (states/eV f.u.) | Θ_D (K) from low- T | Θ_D (K) from all T | Θ_R (K) from $\rho(T)$ |
|----------------------------|--|-------------------------------------|---------------------------------------|--|---------------------------------|--------------------------------|----------------------------------|
| CaPd_2As_2 | 6.52(2) | 0.463(6) | 6.8(4) | 1.87(1) | 276(1) | 252(2) | 135(3) |
| SrPd_2As_2 | 6.43(3) | 0.369(8) | 3.7(5) | 1.89(1) | 298(3) | 245(3) | 170(3) |
| BaPd_2As_2 | 4.79(2) | 0.638(5) | 4.0(3) | 2.03(1) | 248(1) | 227(2) | 114(1) |

Eq. (3), shown as the blue curve in Fig. 5(b), gives $\gamma_n = 6.52(2)$ mJ/mol K², $\beta = 0.463(6)$ mJ/mol K⁴ and $\delta = 6.8(4)$ $\mu\text{J/mol K}^6$. We estimate the Debye temperature Θ_D from β using the relation⁵⁵

$$\Theta_D = \left(\frac{12\pi^4 R n}{5\beta} \right)^{1/3}, \quad (4)$$

where R is the molar gas constant and $n = 5$ is the number of atoms per formula unit (f.u.), yielding $\Theta_D = 276(1)$ K.

The measured normal-state $C_p(T = 300$ K) = 123 J/mol K in Fig. 4 is close to the expected classical Dulong-Petit high- T limiting value $C_V = 3nR = 15R = 124.7$ J/mol K at constant volume V due to acoustic lattice vibrations.^{55,56} Our normal-state $C_p(T)$ data for the T range 2.5 K $\leq T \leq 300$ K were fitted by the sum of the above electronic term $\gamma_n T$ and the Debye model lattice heat capacity $C_V \text{Debye}(T)$ per mole of atoms due to acoustic lattice vibrations according to

$$C_p(T) = \gamma_n T + nC_p(T = \Theta_D)C_V \text{Debye}(T/\Theta_D), \quad (5a)$$

where⁵⁶

$$C_V \text{Debye}(T/\Theta_D) = 9R \left(\frac{T}{\Theta_D} \right)^3 \int_0^{\Theta_D/T} \frac{x^4 e^x}{(e^x - 1)^2} dx \quad (5b)$$

and

$$\begin{aligned} C_V \text{Debye}(T/\Theta_D = 1) &= 9R \int_0^1 \frac{x^4 e^x}{(e^x - 1)^2} dx \quad (5c) \\ &\approx 1.381730 R. \end{aligned}$$

The integral in Eq. (5c) can be obtained in closed form but the expression is cumbersome. When carrying out the least-squares fit of the experimental $C_p(T)$ data by Eqs. (5) we used the high-accuracy analytic Padé approximant for $C_V \text{Debye}(T/\Theta_D)$ in Eq. (5b) that we formulated in Ref. 54 that greatly simplifies the fit. The fit was carried out using the fixed value $\gamma_n = 6.52$ mJ/mol K² obtained above. Thus Θ_D as the only adjustable parameter. The fit yielded $\Theta_D = 252(2)$ K and is shown by the red curve in Fig. 4. This value of Θ_D is close to but slightly smaller than the value $\Theta_D = 276(1)$ K obtained above from analysis of the low- T C_p data. Such differences are expected due to the T dependence of Θ_D .^{54,56}

We estimate the density of states at the Fermi level for both spin directions $\mathcal{D}(E_F)$ from γ_n using the relation⁵⁵

$$\gamma_n = \gamma_0(1 + \lambda_{e-\text{ph}}), \quad \gamma_0 = \frac{\pi^2 k_B^2}{3} \mathcal{D}(E_F), \quad (6)$$

where γ_0 is the bare (LDA band-structure) Sommerfeld coefficient and $\lambda_{e-\text{ph}}$ is the electron-phonon coupling constant. The latter parameter can be estimated from McMillan's theory⁵⁷ for the electron-phonon mechanism of superconductivity and is related to Θ_D and T_c by

$$\lambda_{e-\text{ph}} = \frac{1.04 + \mu^* \ln(\Theta_D/1.45 T_c)}{(1 - 0.62\mu^*) \ln(\Theta_D/1.45 T_c) - 1.04}. \quad (7)$$

Here μ^* is the repulsive screened Coulomb parameter having a value between 0.1 and 0.15 and is usually taken as $\mu^* = 0.13$. With this value of μ^* together with $T_c = 1.27$ K and $\Theta_D = 276$ K as determined above (Table IV), Eqs. (6) and (7) yield

$$\lambda_{e-\text{ph}} = 0.474, \quad \gamma_0 = 4.42 \frac{\text{mJ}}{\text{mol K}^2}. \quad (8)$$

The relatively small value of $\lambda_{e-\text{ph}}$ implies weak-coupling superconductivity in CaPd_2As_2 . The value of $\mathcal{D}(E_F)$ is obtained from the value of γ_0 and Eq. (6) to be $\mathcal{D}(E_F) = 1.87(1)$ states/eV f.u. for both spin directions.

The $\mathcal{D}(E_F)$ and ρ_0 can be used to estimate the mean free path ℓ for conduction carrier scattering at low T . In a single-band quasi-free electron Fermi gas model the Fermi velocity (speed) v_F is⁵⁵

$$v_F = \frac{\pi^2 \hbar^3}{m^* V_{\text{f.u.}}} \mathcal{D}(E_F), \quad (9)$$

where m^* is the effective mass of the current carriers, $V_{\text{f.u.}} = V_{\text{cell}}/2$ from Table I is the volume per formula unit and \hbar is Planck's constant divided by 2π . Assuming $m^* = m_e$ where m_e is the free electron mass, we obtain

$$v_F = 1.76 \times 10^8 \text{ cm/s.} \quad (10)$$

The mean free path $\ell = v_F \tau$, where τ is the mean free scattering time, is obtained from v_F using⁵⁵

$$\ell = 3\pi^2 \left(\frac{\hbar}{e^2 \rho_0} \right) \left(\frac{\hbar}{m^* v_F} \right)^2, \quad (11)$$

where $\hbar/e^2 = 4108 \Omega$. Using $\rho_0 = 34.6 \mu\Omega \text{ cm}$ (for crystal #2), $m^* = m_e$ and the value of v_F in Eq. (10), Eq. (11) gives

$$\ell = 1.52 \text{ nm}, \quad (12)$$

which is only 3.6 in-plane lattice constants (Table I).

The plasma angular frequency ω_p of the conduction carriers can be estimated using the 3D quasi-free-electron single-band relation

$$n = \frac{1}{3\pi^2} \left(\frac{m^* v_F}{\hbar} \right)^3, \quad (13)$$

yielding⁵⁵

$$\omega_p^2 = \frac{4\pi n e^2}{m^*} = \frac{4(m^* e)^2 (v_F/\hbar)^3}{3\pi}. \quad (14)$$

Using $m^* = m_e$ and v_F from Eq. (10) gives

$$\omega_p = 1.94 \times 10^{16} \text{ rad/s}. \quad (15)$$

The superconducting London penetration depth in the clean limit at $T = 0$, $\lambda_L(0)$, is a normal-state property given by^{46,58}

$$\lambda_L(0) = \frac{c}{\omega_p}, \quad (16)$$

where c is the speed of light in vacuum. The value of ω_p in Eq. (15) gives

$$\lambda_L(0) = 1.54 \times 10^{-6} \text{ cm} = 15.4 \text{ nm}. \quad (17)$$

However, we will see in the following section that CaPd_2As_2 is in the dirty limit and not in the clean limit that was treated by BCS, where the actual penetration depth is much larger than $\lambda_L(0)$.

The normal-state parameters obtained from the above analyses of $C_p(T)$ for CaPd_2As_2 are summarized in Tables IV and V together with those obtained below for the other two compounds discussed in this paper.

The Debye temperatures Θ_R in Table III obtained for the three compounds from analyses of the respective $\rho(T)$ data are also listed in Table IV for comparison. The large discrepancies between the values of Θ_D and Θ_R for each compound indicate that the assumptions⁵⁴ of the BG theory are violated in the APd_2As_2 compounds. The BG theory ignores Umklapp carrier scattering. Furthermore, if the Fermi wave vector k_F is significantly smaller than the Debye wave vector k_D , one might expect Θ_D and Θ_R to be significantly different. Furthermore, a mechanism such as electron-electron scattering in addition to the electron-phonon scattering assumed in the BG theory could contribute to the T dependence of ρ .

2. Superconducting State Properties

The electronic contribution $C_e(T)$ to $C_p(T)$ of CaPd_2As_2 obtained at low T by subtracting the low- T

phonon contribution $\beta T^3 + \delta T^5$ from $C_p(T)$ is shown in Fig. 6(a). The large sharp jump ΔC_e in C_e at $T_c = 1.27(3) \text{ K}$ indicates that the superconductivity in CaPd_2As_2 is a bulk effect, confirmed below. The vertical heat capacity jump indicated by the vertical dotted line in Fig. 6(b) yields $\Delta C_e/T_c = 7.4(2) \text{ mJ/mol K}^2$ and hence $\Delta C_e = 9.4(3) \text{ mJ/mol K}$. Using the normal state $\gamma_n = 6.52(2) \text{ mJ/mol K}^2$ from Table IV, one obtains $\Delta C_e/\gamma_n T_c = 1.14(3)$ which is much smaller than the BCS value $\Delta C_e/\gamma_n T_c = 1.43$ in the weak-coupling limit.^{46,58} Because the bulk superconducting transition in $C_e(T)$ is very sharp, we infer that the reduction in $\Delta C_e/\gamma_n T_c$ from the BCS value is intrinsic. This reduction can happen if the superconducting gap (order parameter) is anisotropic in wave vector space, either from anisotropy in the gap on a single Fermi surface⁴⁶ or from multiple bands with distinct Fermi surfaces, each with a different isotropic or anisotropic gap,⁵⁹ as discussed in the context of the α -model below.

The Value of α within the α -Model

For simplicity, we analyze the zero-field superconducting state thermodynamic data for CaPd_2As_2 within the framework of the so-called α -model of the BCS theory of superconductivity,^{46,60,61} where $\alpha \equiv \Delta(0)/k_B T_c$. In this model the normalized gap $\tilde{\Delta}(T) \equiv \Delta(T)/\Delta(0)$ is the same as in the BCS theory which is calculated from the BCS gap equation^{46,60} with $\alpha = \alpha_{\text{BCS}}$ where

$$\alpha_{\text{BCS}} = \pi e^{-\gamma_E} \approx 1.7639 \quad (18)$$

and $\gamma_E \approx 0.5772$ is Euler's constant. However, for calculating the thermodynamic properties one uses a variable α parameter, which represents an inconsistency in the model, but which allows one to fit superconducting state thermodynamic data that deviate from the BCS predictions. The superconducting and normal state electronic entropies at T_c are the same, as in the BCS model, so the superconducting transition is still second order with no latent heat. One can interpret the quantitatively determined deviations from the BCS predictions in terms of other models and theories. For example, values $\alpha > \alpha_{\text{BCS}}$ can arise from the presence of strong electron-phonon coupling in contrast to the weak-coupling assumption in the BCS theory,⁶² whereas $\alpha < \alpha_{\text{BCS}}$ can occur from gap anisotropy in momentum space⁴⁶ which we therefore assume is responsible for the reduced heat capacity jump in CaPd_2As_2 compared to the BCS theory prediction.

The value of α is related to the heat capacity jump at T_c by⁴⁶

$$\begin{aligned} \frac{\Delta C_e(T_c)}{\gamma_n T_c} &= \left. \frac{\Delta C_e(T_c)}{\gamma_n T_c} \right|_{\text{BCS}} \left(\frac{\alpha}{\alpha_{\text{BCS}}} \right)^2 \\ &= \frac{12}{7\zeta(3)} \left(\frac{\alpha}{\alpha_{\text{BCS}}} \right)^2 \approx 1.426 \left(\frac{\alpha}{\alpha_{\text{BCS}}} \right)^2, \end{aligned} \quad (19)$$

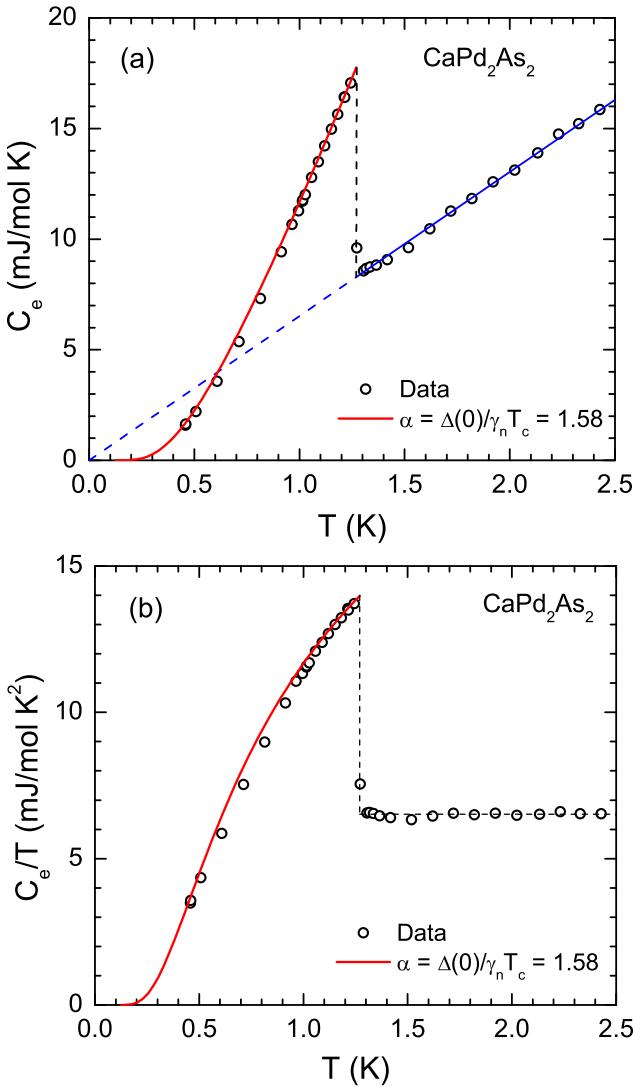


FIG. 6: (Color online) (a) Electronic contribution C_e to the heat capacity versus temperature T of CaPd₂As₂. (b) C_e/T versus T . The solid red curve in each figure is the theoretical prediction of the α -model in Eq. (21a) for $\alpha = 1.58$. The BCS value is $\alpha_{\text{BCS}} \approx 1.764$. The normal-state heat capacity is $C_{\text{en}} = \gamma_{\text{n}}T$ with $\gamma_{\text{n}} = 6.52 \text{ mJ/mol K}^2$. In (a), this normal-state contribution is the blue straight line and the extrapolation to low T is the dashed blue line. In (b), the normal-state behavior is $C_{\text{en}}/T = \gamma_{\text{n}}$.

where $\zeta(x)$ is the Riemann zeta function. Inserting our normalized experimental heat capacity jump value into Eq. (19) gives

$$\alpha = 1.58(2), \quad (20)$$

which is significantly smaller than the BCS value of 1.764.

The temperature dependence of the superconducting-state electronic heat capacity is calculated within the α -

model using⁴⁶

$$\frac{C_{\text{es}}(t)}{\gamma_{\text{n}}T_{\text{c}}} = \frac{6\alpha^3}{\pi^2 t} \int_0^\infty f(1-f) \left(\frac{\tilde{E}^2}{t} - \frac{1}{2} \frac{d\tilde{\Delta}^2}{dt} \right) d\tilde{\epsilon}, \quad (21\text{a})$$

where $t = T/T_{\text{c}}$, the normalized normal-state electron energy is $\tilde{\epsilon} = \epsilon/\Delta(0)$, the normalized excited quasiparticle (electron and hole) energy is

$$\tilde{E} = \frac{E}{\Delta(0)} = \sqrt{\tilde{\epsilon}^2 + \tilde{\Delta}^2}, \quad (21\text{b})$$

and the Fermi-Dirac distribution function in the dimensionless variables is (with $E_{\text{F}} \equiv 0$)

$$f \equiv f(\alpha, \tilde{E}, t) = \frac{1}{e^{\alpha\tilde{E}/t} + 1} \quad (21\text{c})$$

$$\text{with } \frac{E}{k_{\text{B}}T} = \frac{\alpha\tilde{E}}{t}.$$

The t -dependent $\tilde{\Delta}(t)$ and $d\tilde{\Delta}(t)/dt^2$ are calculated as described in Ref. 46.

The solid red curves in Figs. 6(a) and 6(b) are the theoretical predictions for $C_{\text{es}}(T)$ and $C_{\text{es}}(T)/T$, respectively, calculated from Eq. (21a) using $\alpha = 1.58$ and are seen to be in good agreement with the data. The agreement of the lowest- T data with the theory indicates that there is no residual electronic specific heat for $T \rightarrow 0$, which in turn indicates that the entire sample is superconducting with a single nodeless s -wave gap and with a single T_{c} .

Thermodynamic Critical Field H_{c}

The experimental thermodynamic critical field H_{c} versus T of a superconductor can be estimated using the zero-field $C_{\text{e}}(T)$ data via the electronic entropy difference between the normal (S_{en}) and superconducting (S_{es}) states per unit volume at $H = 0$ according to the Clausius-Clapeyron-like relation^{58,63}

$$S_{\text{en}}(T) - S_{\text{es}}(T) = -\frac{1}{8\pi} \frac{dH_{\text{c}}^2(T)}{dT}. \quad (22\text{a})$$

which, with $S_{\text{e}}(T') = \int_0^{T'} [C_{\text{e}}(T'')/T''] dT''$, yields

$$H_{\text{c}}^2(T) = 8\pi \int_T^{T_{\text{c}}} [S_{\text{en}}(T') - S_{\text{es}}(T')] dT'. \quad (22\text{b})$$

In cgs units, H_{c} is expressed in units of Oe, where $1 \text{ Oe}^2 = 1 \text{ erg/cm}^3$, so $S_{\text{en}}(T') = \gamma_{\text{n}}V T'$ is in units of $\text{erg/cm}^3 \text{ K}$. The Sommerfeld coefficient $\gamma_{\text{n}}V$ in units of $\text{erg/cm}^3 \text{ K}^2$ is calculated from the above Sommerfeld coefficient γ_{n} in units of $\text{mJ/mol K}^2 = 10^4 \text{ erg/mol K}^2$ according to

$$\gamma_{\text{n}}V = \frac{\gamma_{\text{n}}}{V_{\text{M}}}, \quad (23)$$

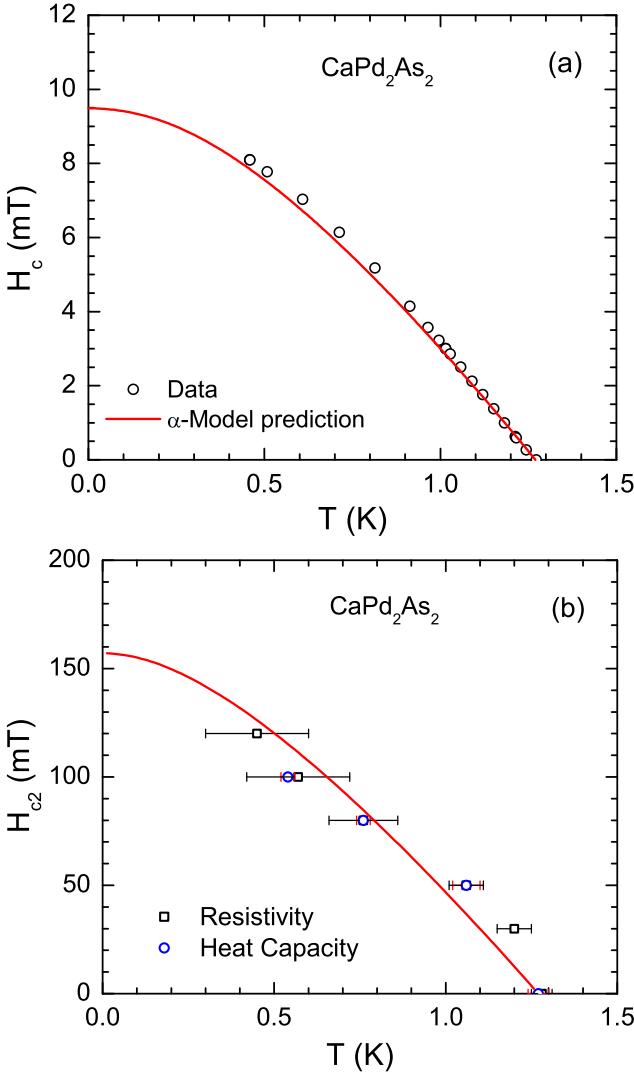


FIG. 7: (Color online) (a) Thermodynamic critical field H_c versus temperature T obtained for CaPd_2As_2 from the experimentally derived electronic heat capacity $C_e(T)$ data using Eqs. (22) (open circles) and the theoretical prediction of the α -model^{46,61} using $T_c = 1.27$ K, $\alpha = 1.58$ and $\gamma_n = 6.52$ mJ/mol K² in Eqs. (24) and (25) (red curve). (b) Upper critical magnetic field $H_{c2}(T)$ of CaPd_2As_2 determined from the electrical resistivity $\rho(T, H)$ (black open squares) and heat capacity $C_p(T, H)$ (blue open circles) data in Figs. 3(b) and 5(a), respectively. The red curve is the prediction for $H_{c2}(T)$ by the WHH theory⁶⁵ in Eqs. (30) for $dH_{c2}(T)/dT|_{T=T_c} = -0.18$ T/K, $\alpha_M = 0.13$, and $\lambda_{so} = 0$.

where V_M is the molar volume in units of cm^3/mol . For CaPd_2As_2 , our values $\gamma_n = 6.52$ mJ/mol K² and $V_M = 55.7$ cm^3/mol from Table I give $\gamma_{nV} = 1170$ erg/cm³ K². The experimental $H_c(T)$ data obtained from Eqs. (22) are plotted as open circles in Fig. 7(a).

In the α -model, the thermodynamic critical field at

$T = 0$ is given by⁴⁶

$$\frac{H_c(0)}{(\gamma_{nV} T_c^2)^{1/2}} = \sqrt{\frac{6}{\pi}} \alpha \approx 1.382 \alpha. \quad (24)$$

Using our values of γ_{nV} , $\alpha = 1.58$, and $T_c = 1.27$ K gives $H_c(0) = 9.5$ mT. The T dependence of H_c is calculated from⁴⁶

$$\begin{aligned} \frac{H_c^2(t)}{H_c^2(0)} &= \frac{4\pi^2}{3\alpha^2} \int_t^1 \left[\frac{S_{\text{en}}(t')}{\gamma_{nV} T_c} - \frac{S_{\text{es}}(t')}{\gamma_{nV} T_c} \right] dt' \\ &= \frac{4\pi^2}{3\alpha^2} \int_t^1 \left[t' - \frac{S_{\text{es}}(t')}{\gamma_{nV} T_c} \right] dt', \end{aligned} \quad (25a)$$

where the normal-state electronic entropy is $S_{\text{en}}(t')/\gamma_{nV} T_c = t'$, and the superconducting state entropy is obtained from

$$\frac{S_{\text{es}}(t)}{\gamma_{nV} T_c} = \frac{6\alpha^2}{\pi^2 t} \int_0^\infty f(\alpha, \tilde{E}, t) \left(\tilde{E} + \frac{\tilde{\epsilon}^2}{\tilde{E}} \right) d\tilde{\epsilon}. \quad (25b)$$

The resulting $H_c(T)$ calculated for the above values of $H_c(0)$, α , γ_{nV} and T_c is shown by the red curve in Fig. 7(a). Good agreement is observed between the temperature dependence of the data and the theoretical prediction of the α -model, although the calculated zero-temperature value appears to be a bit low.

Upper Critical Field H_{c2}

The $\rho(T)$ data in Fig. 3(b) and the $C_p(T)$ data in Fig. 5(a) for CaPd_2As_2 in fields aligned along the c axis yield the T -dependence of the upper critical field H_{c2} shown in Fig. 7(b). One sees that $H_{c2}(T \rightarrow 0)$ is more than an order of magnitude larger than $H_c(0) = 9.5$ mT determined above, indicating that CaPd_2As_2 is a type-II superconductor. Although the demagnetization factor of the plate-like crystal is large for $H \parallel c$, this has no influence on the present discussion because we only discuss the high-field behavior at the boundary with the normal state, where the magnetization is small.

For a one-band type-II BCS superconductor the orbital critical field H_{c2}^{Orb} at $T = 0$ is given by^{64,65}

$$H_{c2}^{\text{Orb}}(0) = -A T_c \frac{dH_{c2}(T)}{dT} \Big|_{T=T_c}, \quad (26)$$

where $A = 0.73$ and 0.69 in the clean and dirty limits, respectively. From Fig. 7(b), $dH_{c2}(T)/dT|_{T=T_c} = -0.22(6)$ T/K as determined from the $\rho(T)$ data for $0.8 < T/T_c < 1.0$. Thus for CaPd_2As_2 we estimate $H_{c2}^{\text{Orb}}(0) = 0.20(6)$ T in the clean limit and $H_{c2}^{\text{Orb}}(0) = 0.19(5)$ T in the dirty limit.

The Pauli-limiting upper critical field at $T = 0$, $H_P(0)$, is the maximum possible upper critical field and is the field at which the magnetic field energy of the current carriers is equal to the superconducting condensation

energy.^{66,67} Within the α -model, this is given for spectroscopic splitting factor $g = 2$ by

$$\frac{\mu_B H_P(0)}{k_B T_c} = \frac{\alpha}{\sqrt{2}} \approx 1.2473 \left(\frac{\alpha}{\alpha_{BCS}} \right), \quad (27)$$

where μ_B is the Bohr magneton and α_{BCS} is given in Eq. (18), yielding

$$H_P(0)[T] = 1.86 T_c[K] \left(\frac{\alpha}{\alpha_{BCS}} \right). \quad (28)$$

Taking $T_c = 1.27$ K, $\alpha = 1.58$ from Eq. (20) and $\alpha_{BCS} = 1.7639$ from Eq. (18) gives $H_P(0) = 2.12$ T. Since the measured $H_{c2}(0) \sim 0.15$ T $\sim 0.07 H_P(0)$ [see Fig. 7(b)], the effects of Pauli limiting on H_{c2} should be minimal. The Maki parameter α_M expresses the relative magnitudes of the orbital and Pauli limiting H_{c2} values as⁶⁸

$$\alpha_M = \sqrt{2} \frac{H_{c2}^{\text{Orb}}(0)}{H_P(0)}, \quad (29)$$

which gives $\alpha_M = 0.13$ for CaPd₂As₂.

To include the influence of Pauli limiting and spin-orbit scattering of quasiparticles on H_{c2} , we analyzed the $H_{c2}(T)$ data within the Werthamer, Helfand and Hohenberg (WHH) theory for a one-band type-II dirty-limit superconductor which calculates H_{c2} in terms of the orbital, spin-orbit scattering and Pauli spin paramagnetism contributions in dimensionless variables as⁶⁵

$$\ln \frac{1}{t} = \sum_{\nu=-\infty}^{\infty} \left\{ \frac{1}{|2\nu+1|} - \left[|2\nu+1| + \frac{\bar{h}}{t} + \frac{(\alpha_M \bar{h}/t)^2}{|2\nu+1| + (\bar{h} + \lambda_{\text{so}})/t} \right]^{-1} \right\}, \quad (30a)$$

where $t = T/T_c$, λ_{so} is the spin-orbit scattering parameter and

$$\bar{h} = - \left(\frac{4}{\pi^2} \right) \frac{H_{c2}(T)/T_c}{dH_{c2}(T)/dT|_{T=T_c}}. \quad (30b)$$

WHH state that the applicability of their theory to a specific superconductor can be tested by comparing the value of α_M calculated from Eq. (29) with the value obtained from their alternative expression⁶⁵

$$\alpha_M = -0.528 \frac{dH_{c2}(T)}{dT} \Big|_{T=T_c}, \quad (31)$$

where the derivative is in units of T/K. Using our value

$$\frac{dH_{c2}(T)}{dT} \Big|_{T=T_c} = -0.22(6) \frac{\text{T}}{\text{K}} \quad (32)$$

obtained from Fig. 7(b), Eq. (31) gives $\alpha_M = 0.12(3)$, which is indeed in agreement with the above estimate $\alpha_M = 0.13$, thus indicating that the WHH theory is appropriate for fitting our $H_{c2}(T)$ data. Reasonable

agreement of $H_{c2}(T)$ with the WHH theory prediction for $\alpha_M = 0.13$ was obtained from Eq. (30) with $\lambda_{\text{so}} = 0$ and $dH_{c2}(T)/dT|_{T=T_c} = -0.18$ T/K as shown in Fig. 7(b), where $H_{c2}(0) = 157$ mT. The same value of $dH_{c2}(T)/dT|_{T=T_c}$ is obtained from the dirty-limit relation⁶⁹ $dH_{c2}(T)/dT|_{T=T_c} = 4.48 \times 10^4 \gamma_{\text{nV}} \rho_0$, where ρ is in units of $\Omega \text{ cm}$, indicating that CaPd₂As₂ is in the dirty limit as further documented below.

Ginzburg-Landau Parameter

The Ginzburg-Landau parameter κ_{GL} can be estimated from the relation⁵⁸

$$\kappa_{\text{GL}} = \frac{H_{c2}}{\sqrt{2} H_c}. \quad (33)$$

Using $H_{c2} = 157$ mT and $H_c = 9.5$ mT gives $\kappa_{\text{GL}} = 11.7 \gg 1/\sqrt{2}$, characterizing CaPd₂As₂ as a type-II superconductor. An estimate of the lower critical field H_{c1} is then obtained from⁵⁸

$$H_{c1} = H_c \frac{\ln \kappa_{\text{GL}}}{\sqrt{2} \kappa_{\text{GL}}}, \quad (34)$$

which for $H_c(0) = 9.5$ mT and $\kappa_{\text{GL}} = 11.7$ gives $H_{c1}(0) = 1.4$ mT.

The Ginzburg-Landau coherence length at $T = 0$, $\xi(0)$, can be estimated from^{58,63}

$$H_{c2}(0) = \frac{\Phi_0}{2\pi\xi(0)^2}, \quad (35)$$

where $\Phi_0 = 2.07 \times 10^{-7}$ G cm² is the flux quantum. Using $H_{c2} = 157$ mT this gives

$$\xi(0) = 45.8 \text{ nm}. \quad (36)$$

This $\xi(0)$ is much larger than the mean free path $\ell = 1.52$ nm in Eq. (12) which indicates that CaPd₂As₂ is in the dirty limit.

In the dirty limit the penetration depth at $T \rightarrow 0$ in the notation of Tinkham is given by⁵⁸

$$\lambda_{\text{eff}}(0) = \lambda_L(0) \sqrt{1 + \frac{\xi_0}{\ell}} \quad (\text{dirty limit}). \quad (37)$$

The T dependence of ξ is given by⁵⁸

$$\frac{\xi(T)}{\xi_0} = \frac{\pi}{2\sqrt{3}} \frac{H_c(0)}{H_c(T)} \frac{\lambda_L(0)}{\lambda_{\text{eff}}(T)}, \quad (38)$$

yielding the relationship between the zero-temperature Ginzburg-Landau $\xi(0)$ and the BCS ξ_0 as

$$\frac{\xi(0)}{\xi_0} = \frac{\pi}{2\sqrt{3}} \frac{\lambda_L(0)}{\lambda_{\text{eff}}(0)}. \quad (39)$$

Combining Eqs. (37) and (39) gives

$$\frac{\xi(0)}{\xi_0} = \frac{\pi}{2\sqrt{3} \left(1 + \frac{\xi_0}{\ell} \right)} \quad (\text{dirty limit}). \quad (40)$$

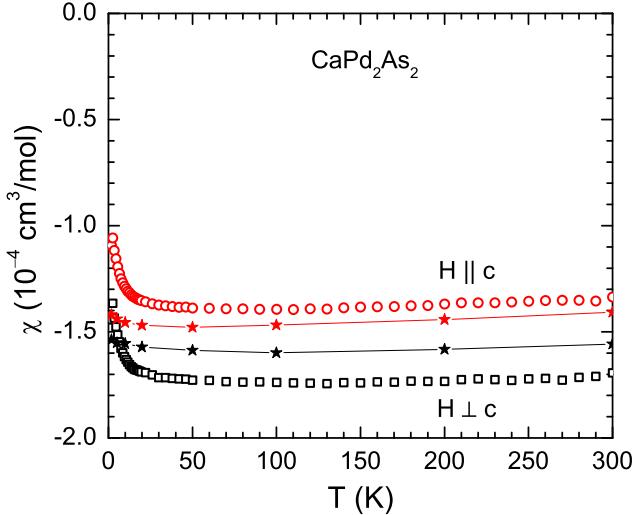


FIG. 8: (Color online) Zero-field-cooled magnetic susceptibility χ of a CaPd_2As_2 single crystal versus temperature T measured in a magnetic field $H = 3.0$ T applied along the c -axis (χ_c , $H \parallel c$) and in the ab -plane (χ_{ab} , $H \perp c$). The filled stars represent the intrinsic χ obtained from fitting $M(H)$ isotherm data in the Appendix by Eq. (A.2a) which are more accurate than the temperature-scanned data at fixed field. The lines joining the stars are guides to the eye.

Substituting the above values for $\xi(0)$ in Eq. (36) and ℓ in Eq. (12) into Eq. (40) and solving for ξ_0 gives $\xi_0 = 1690$ nm. Then using $\lambda_L(0) = 15.4$ nm, $\xi_0 = 1690$ nm and $\ell = 1.52$ nm, Eq. (37) gives $\lambda_{\text{eff}}(0) = 510$ nm in the dirty limit, which is of the same order as the value of $210(60)$ nm obtained from the penetration depth measurements in Sec. VII below.

The BCS coherence length is related to the Fermi velocity within the α -model by⁴⁶

$$\xi_0 = \frac{\hbar v_F}{\pi \Delta(0)} = \left(\frac{1}{\pi \alpha} \right) \frac{\hbar v_F}{k_B T_c}. \quad (41)$$

This allows an additional estimate of the Fermi velocity which for $\alpha = 1.58$ and $\xi_0 = 1690$ nm yields $v_F = 1.40 \times 10^8$ cm/s. This value of v_F is close to the value $v_F = 1.76 \times 10^8$ cm/s in Eq. (10) obtained from $\mathcal{D}(E_F)$, indicating the self-consistency of our modeling.

A summary of the measured and derived superconducting state parameters for CaPd_2As_2 is given in Table V.

C. Magnetization and Magnetic Susceptibility

Zero-field-cooled (ZFC) $\chi(T) \equiv M(T)/H$ data for a CaPd_2As_2 crystal versus T in a magnetic field $H = 3.0$ T applied along the c -axis (χ_c , $H \parallel c$) and in the ab -plane (χ_{ab} , $H \perp c$) are shown in Fig. 8. The data for both directions of H are strongly diamagnetic and nearly independent of T except for the Curie-like upturns at low- T which were found from analysis of $M(H)$

TABLE V: Measured and derived superconducting and relevant normal state parameters for CaPd_2As_2 . T_c : bulk superconducting transition temperature; γ_n : observed Sommerfeld coefficient of the linear term in the low- T normal-state heat capacity; $\lambda_{e-\text{ph}}$: electron-phonon coupling constant; γ_0 : bare Sommerfeld coefficient; ΔC_e : heat capacity jump at T_c ; $\alpha = \Delta(0)/k_B T_c$; Δ : superconducting order parameter; α_M : Maki parameter; H_c , H_P , H_{c1} , H_{c2}^{Orb} , H_{c2} : thermodynamic, Paul limiting upper critical, lower critical, orbital upper critical, and fitted upper critical magnetic fields, respectively; κ_{GL} : Ginzburg-Landau parameter; ξ : Ginzburg-Landau coherence length; ξ_0 : BCS superconducting coherence length; ℓ : electronic mean-free path at low T ; ω_p : angular plasma frequency; λ_L : London penetration depth; λ_{eff} : magnetic penetration depth. The value of $\lambda_{\text{eff}}^{\text{obs}}(0)$ is determined from the magnetic penetration depth measurements.

| CaPd ₂ As ₂ property | value |
|--|----------|
| T_c (K) | 1.27(3) |
| γ_n (mJ/mol K ²) | 6.52(2) |
| $\lambda_{e-\text{ph}}$ | 0.474 |
| γ_0 (mJ/mol K ²) | 4.42 |
| ΔC_e (mJ/mol K) | 9.4(3) |
| $\Delta C_e/\gamma_n T_c$ | 1.14(3) |
| α (from $\Delta C_e/\gamma_n T_c$) | 1.58(2) |
| $\Delta(0)/k_B$ (K) (observed) | 2.02(14) |
| α_M | 0.13 |
| $H_c(T = 0)$ (mT) | 9.5 |
| H_P (T) | 2.12 |
| $H_{c1}(T = 0)$ (mT) | 1.4 |
| $H_{c2}^{\text{Orb}}(T = 0)$ (dirty limit) (T) | 0.19(5) |
| $H_{c2}(T = 0)$ (mT) | 157 |
| κ_{GL} | 11.7 |
| $\xi(T = 0)$ (nm) | 45.8 |
| ξ_0 (nm) | 1690 |
| $\ell(m^* = m_e)$ (nm) | 1.52 |
| $\omega_p(m^* = m_e)(10^{16}$ rad/s) | 1.94 |
| $\lambda_L^{\text{calc}}(0)$ (clean limit) (nm) | 15.4 |
| $\lambda_{\text{eff}}^{\text{calc}}(0)$ (dirty limit) (nm) | 510 |
| $\lambda_{\text{eff}}^{\text{obs}}(0)$ (nm) | 210(60) |

isotherms in the Appendix to be due to the presence of a small amount of saturable paramagnetic (PM) impurities. The intrinsic $\chi(T)$ values at several temperatures obtained from the analysis of the $M(H)$ isotherms are shown by filled stars in Fig. 8, which are more accurate than the $\chi(T) = M(T)/H$ data. The χ is anisotropic with $\chi_c > \chi_{ab}$ over the entire T range.

The χ anisotropy in CaPd_2As_2 is different from the anisotropy usually observed in doped and undoped FeAs-based ThCr_2Si_2 -structure compounds, where $\chi_{ab} > \chi_c$ such as in BaFe_2As_2 .^{10,11} The powder and temperature average of the intrinsic χ obtained from fitting the $M(H)$ isotherms over the T range 20 to 300 K is $\langle \chi \rangle = [2\langle \chi_{ab} \rangle + \langle \chi_c \rangle]/3 = -1.5 \times 10^{-4}$ cm³/mol.

The diamagnetic susceptibilities in Fig. 8 seem to be rather large. For the purpose of comparing the diamagnetic susceptibilities of different materials, a comparison of the thermodynamic dimensionless magnetic susceptibility per unit volume χ_V (volume susceptibil-

ity) is most appropriate. Using the molar volume $V_M = 55.7 \text{ cm}^3/\text{mol}$ for CaPd_2As_2 in Table I and $\chi_{ab}(100 \text{ K}) = -1.6 \times 10^{-4} \text{ cm}^3/\text{mol}$ from Fig. 8 (black star), one obtains $\chi_{Vab} = \chi_{ab}/V_M$ in the ab plane as

$$\chi_{Vab}(100 \text{ K}) = -0.29 \times 10^{-5} \quad (\text{CaPd}_2\text{As}_2). \quad (42)$$

This value can be compared with the respective values for elemental Bi and C (graphite) that are well-known for their exceptionally strong diamagnetism. Bi has a rhombohedral crystal structure with a mass density $\rho_m = 9.8 \text{ g/cm}^3$ and a gram susceptibility in the hexagonal ab plane $\chi_{g ab}(100 \text{ K}) = -1.9 \times 10^{-6} \text{ cm}^3/\text{g}$.⁷⁰ The volume susceptibility $\chi_V = \rho_m \chi_g$ is then

$$\chi_{Vab}(100 \text{ K}) = -1.9 \times 10^{-5} \quad (\text{Bi}). \quad (43)$$

On the other hand, using $\rho_m = 2.27 \text{ g/cm}^3$ for hexagonal highly-oriented pyrolytic graphite (HOPG) and $\chi_{g c}(100 \text{ K}) = -2.3 \times 10^{-5} \text{ cm}^3/\text{g}$,⁷¹ one obtains

$$\chi_{Vc}(100 \text{ K}) = -5.2 \times 10^{-5} \quad (\text{C, HOPG}). \quad (44)$$

These values for Bi and graphite are about 6.5 and 18 times more diamagnetic than the value for CaPd_2As_2 in Eq. (42), respectively. However, these three values are all much less diamagnetic than the value $\chi_V = -1/4\pi \approx -0.0796$ for the diamagnetic susceptibility of a superconductor at low fields with zero demagnetization factor due to complete exclusion of the magnetic induction from the interior (except within a magnetic field penetration depth of the surface).

The different contributions to the intrinsic χ are

$$\chi = \chi_{\text{core}} + \chi_{\text{VV}} + \chi_{\text{L}} + \chi_{\text{P}}, \quad (45)$$

where the first three terms are orbital susceptibilities and the last term is the Pauli spin susceptibility of the conduction carriers. χ_{core} is the isotropic diamagnetic susceptibility of localized core electrons, χ_{VV} is the generally anisotropic paramagnetic Van Vleck susceptibility, and χ_{L} is the generally isotropic Landau diamagnetic susceptibility of the conduction carriers.

The χ_{core} is estimated using atomic diamagnetic susceptibilities⁷² which gives $\chi_{\text{core}} = -1.78 \times 10^{-4} \text{ cm}^3/\text{mol}$. The χ_{P} is related to $\mathcal{D}(E_F)$ by^{11,73}

$$\chi_{\text{P}} = \frac{g^2}{4} \mu_B^2 \mathcal{D}(E_F). \quad (46)$$

Then using $g = 2$ and $\mathcal{D}(E_F) = 1.87 \text{ states/eV f.u.}$ for both spin directions, from Table IV we obtain $\chi_{\text{P}} = 6.0 \times 10^{-5} \text{ cm}^3/\text{mol}$. The χ_{L} is related to χ_{P} by^{73,74}

$$\chi_{\text{L}} = -\frac{1}{3} \left(\frac{m_e}{m^*} \right)^2 \chi_{\text{P}}, \quad (47)$$

where m^* is the effective mass and m_e is the electron mass. Assuming $m^* = m_e$ we obtain $\chi_{\text{L}} = -2.0 \times 10^{-5} \text{ cm}^3/\text{mol}$ from the above value of χ_{P} . Then χ_{VV} is obtained by subtracting these three contributions from

TABLE VI: Estimated contributions to the intrinsic angle- and temperature-averaged magnetic susceptibilities $\langle \chi \rangle$ of APd_2As_2 ($A = \text{Ba, Ca, Sr}$) crystals. Here χ_{P} is the Pauli spin susceptibility of the conduction carriers, and the orbital susceptibility contributions are the diamagnetism χ_{core} of the atomic electron cores, the Landau diamagnetism χ_{L} of the conduction carriers and the Van Vleck paramagnetism χ_{VV} . All susceptibilities are in units of $10^{-5} \text{ cm}^3/\text{mol}$. Possible reasons for the unphysical negative value of $\langle \chi_{\text{VV}} \rangle$ for CaPd_2As_2 are discussed in the text.

| Compound | $\langle \chi \rangle$ | χ_{core} | χ_{P} | χ_{L} | $\langle \chi_{\text{VV}} \rangle$ |
|----------------------------|------------------------|----------------------|-------------------|-------------------|------------------------------------|
| CaPd_2As_2 | -15.4 | -17.8 | 6.0 | -2.0 | -1.6 |
| SrPd_2As_2 | -3.9 | -19.3 | 6.0 | -2.0 | 11.4 |
| BaPd_2As_2 | -12.4 | -21.6 | 6.6 | -2.2 | 4.8 |

the measured χ according to Eq. (45). The four contributions to the intrinsic χ are summarized in Table VI, along with corresponding values for SrPd_2As_2 and BaPd_2As_2 determined below.

It is seen in Table VI that the inferred value of χ_{VV} for CaPd_2As_2 is negative, which is unphysical. The reason for this error is not clear. The most likely source of the negative χ_{VV} value is a small error in correcting the total measured magnetic moment for the sample holder contribution, which was up to 40% of the total measured moment. Thus the uncertainty in the measured χ values is of order 10% as discussed in Sec. II. In particular, the negative χ_{VV} is about 8% of the measured moment, and an error of only 4% in the sample holder correction could cause the derived χ_{VV} to be negative.

V. PHYSICAL PROPERTIES OF SrPd_2As_2 CRYSTALS

A. Electrical Resistivity

The in-plane $\rho(T)$ data for SrPd_2As_2 measured on two different crystals #1 and #2 at different H are shown in Fig. 9. Metallic behavior is evident from the T dependence of ρ in Fig. 9(a). The expanded plot of $\rho(T)$ in Fig. 9(b) reveals a superconducting transition at $T_c = 1.5(1) \text{ K}$. The T_c is suppressed with increasing H , as shown. The data in Fig. 9(b) are noisy due to the small sample size and the small voltage signal arising from the small magnitude of the resistivity at low T .

The two crystals were found to have different residual resistivities and RRR values. For crystal #1, $\rho_0(1.8 \text{ K}) = 7.5 \mu\Omega \text{ cm}$ and $\text{RRR} = \rho(300 \text{ K})/\rho(1.8 \text{ K}) \approx 8$, whereas for crystal #2, $\rho_0 = 4.9 \mu\Omega \text{ cm}$ and $\text{RRR} \approx 4$. Since crystal #1 has the higher RRR, we analyzed the $\rho(T)$ data of this crystal in Fig. 9(a) using the BG model. A fit of the $\rho(T)$ data in Fig. 9(a) by Eqs. (2) for $1.8 \text{ K} \leq T \leq 300 \text{ K}$ gives $\rho_0 = 7.57(6) \mu\Omega \text{ cm}$, $\rho(\Theta_R) = 27.6(5) \mu\Omega \text{ cm}$ and $\Theta_R = 170(3) \text{ K}$, where we used our analytic Padé approximant⁵⁴ in place of the integral in Eq. (2a). The good fit obtained is shown by the red curve in Fig. 9(a).

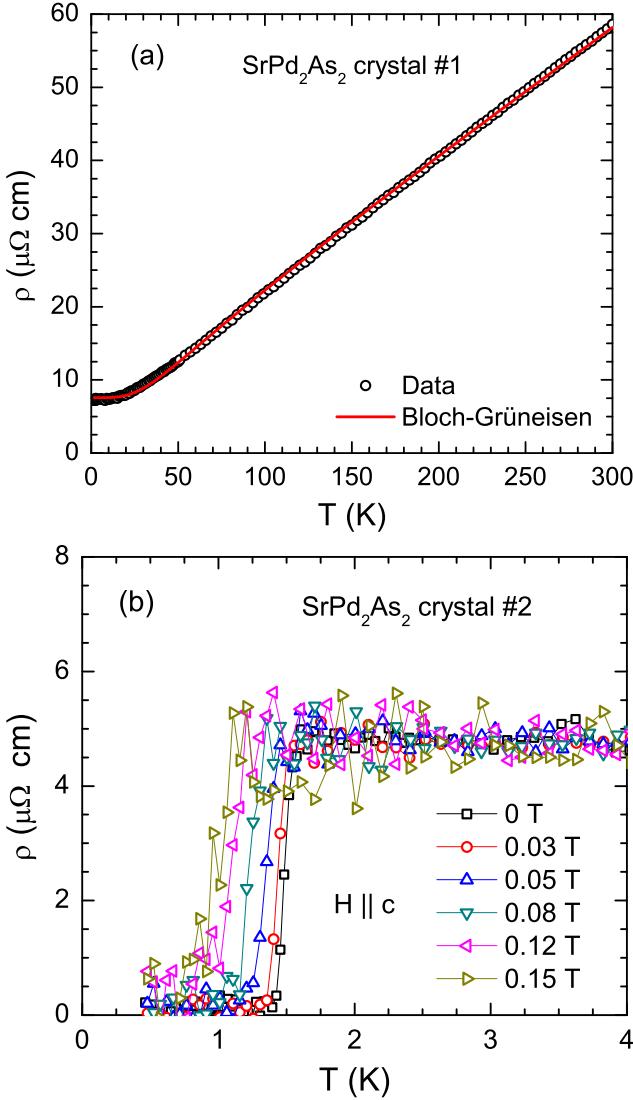


FIG. 9: (Color online) (a) In-plane electrical resistivity ρ of a SrPd_2As_2 crystal (crystal #1) versus temperature T measured in applied magnetic field $H = 0$. The red curve is a fit by the Bloch-Grüneisen model in Eqs. (2). (b) Expanded plot of the low- T $\rho(T)$ data for SrPd_2As_2 crystal #2 for $0.45 \text{ K} \leq T \leq 4 \text{ K}$ showing the superconducting transition for different H applied along the c axis. The noise in the data is due to the small size of the crystal and the small magnitude of ρ at low temperatures.

The value of \mathcal{R} obtained from the value of $\rho(\Theta_R)$ using Eq. (2c) is $\mathcal{R} = 29.2 \mu\Omega \text{ cm}$. The parameters obtained from the fit are summarized in Table III.

B. Heat Capacity

The $C_p(T)$ data for SrPd_2As_2 are shown in Fig. 10. The $C_p(T = 300 \text{ K}) \approx 124 \text{ J/mol K}$ is close to the classical Dulong-Petit high- T limit $C_V = 5R = 124.7 \text{ J/mol K}$. In order to correlate low- T $C_p(T)$ data with $\rho(T)$ data

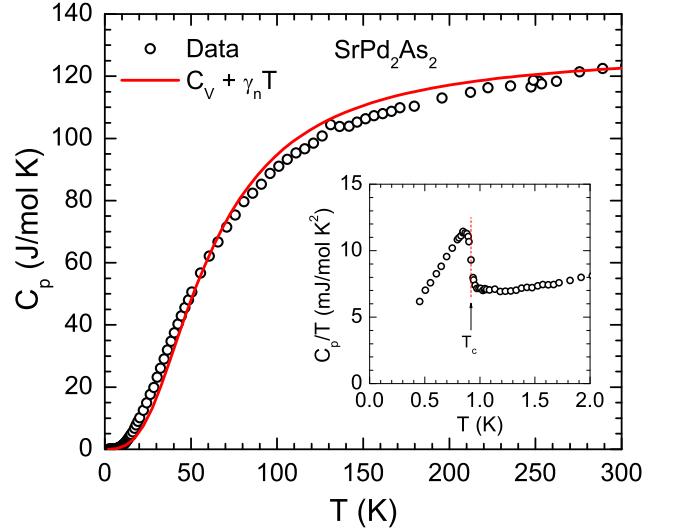


FIG. 10: (Color online) The heat capacity C_p of a SrPd_2As_2 single crystal versus temperature T measured in zero magnetic field H . The red curve is the fitted sum of the contributions from the Debye lattice heat capacity $C_{V,\text{Debye}}(T)$ and predetermined electronic heat capacity $\gamma_n T$ according to Eq. (5a). Inset: Expanded plot of C_p/T versus T for $0.45 \text{ K} \leq T \leq 2.0 \text{ K}$ measured on a different crystal (crystal #2 of Fig. 9) at field $H = 0$. The vertical dotted red line indicates the T_c .

obtained on the same crystal, we also measured the low- T $C_p(T)$ on a different crystal #2 as shown in Fig. 11(a), for which the $\rho(T)$ data are shown in Fig. 9(b). As shown in the inset of Fig. 10, a rather sharp heat capacity jump is observed at $T_c = 0.92(5) \text{ K}$ due to the superconducting transition, where we define T_c to be the transition midpoint. Two important differences are observed between the $C_p(T)$ and $\rho(T)$ data on crystal #2. First, the T_c obtained from the two measurements are different: $T_c = 0.92(5) \text{ K}$ from $C_p(T)$ and $T_c = 1.5(1) \text{ K}$ from $\rho(T)$. Second, while the superconductivity is suppressed to a temperature below 0.45 K by $H = 0.05 \text{ T}$ in $C_p(T)$, superconductivity occurs at $\approx 1 \text{ K}$ even at $H = 0.15 \text{ T}$ in $\rho(T)$. These two observations suggest the presence of surface sheath superconductivity in SrPd_2As_2 which is probed by $\rho(T)$ whereas $C_p(T)$ measures the bulk superconductivity.

A fit of the normal-state $C_p(T)/T$ versus T^2 data using the $H = 0.1 \text{ T}$ data for $0.45 \text{ K} \leq T \leq 4.4 \text{ K}$ and the $H = 0$ data for $1.3 \text{ K} \leq T \leq 4.4 \text{ K}$ in Fig. 11(b) by Eq. (3) (the fitted data from 3.2 K to 4.4 K are not shown) gives $\gamma_n = 6.43(3) \text{ mJ/mol K}^2$, $\beta = 0.369(8) \text{ mJ/mol K}^4$ and $\delta = 3.7(5) \mu\text{J/mol K}^6$ as shown by the red curve. The Debye temperature estimated from β using Eq. (4) is $\Theta_D = 298(3) \text{ K}$. A fit of $C_p(T)$ in Fig. 10 over the entire T range (2 – 300 K) by Eqs. (5) with γ_n fixed to the above value and using the Padé approximant⁵⁴ in place of the Debye function gives $\Theta_D = 245(3) \text{ K}$. The fit is shown by the red curve in Fig. 10. The value of Θ_D is smaller than the

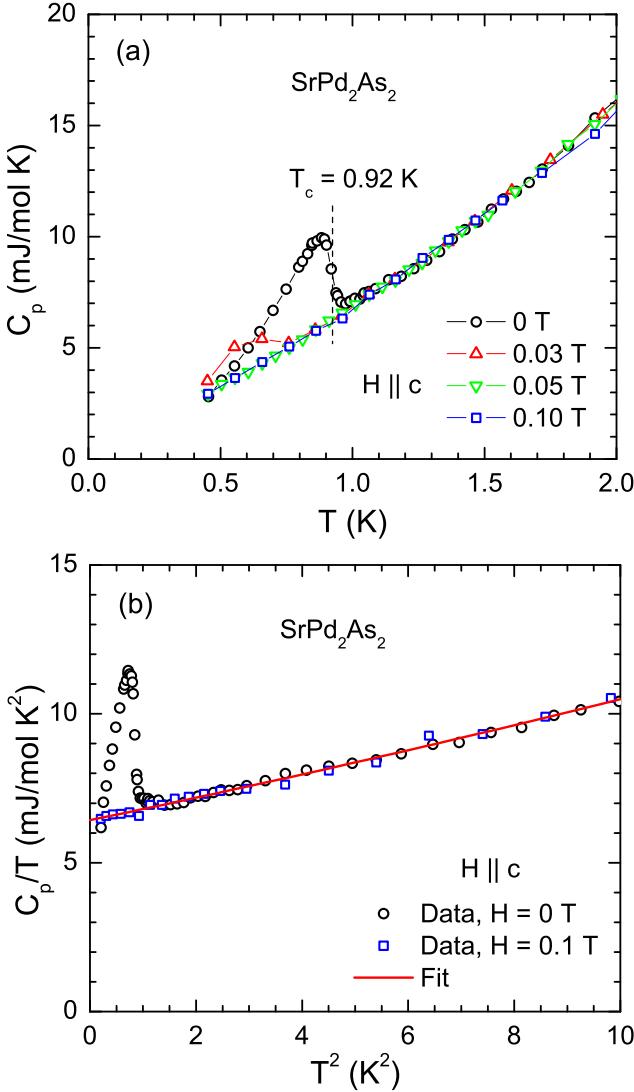


FIG. 11: (Color online) (a) Heat capacity C_p versus temperature T of a SrPd_2As_2 single crystal [crystal # 2 of Fig. 9] for $0.45 \text{ K} \leq T \leq 2.0 \text{ K}$ measured at the indicated values of applied magnetic field H with $H \parallel c$. (b) C_p/T vs. T^2 for $0.45 \text{ K} \leq T \leq 3.2 \text{ K}$ with $H = 0$ and 0.1 T . The red curve is a fit of the $H = 0.1 \text{ T}$ data for $0.45 \text{ K} \leq T \leq 4.4 \text{ K}$ and the $H = 0$ data for $1.3 \text{ K} \leq T \leq 4.4 \text{ K}$ by Eq. (3) (the fitted data from 3.2 K to 4.4 K are not shown).

value of $298(3) \text{ K}$ obtained from the low- T fit, indicating a T -dependent Θ_D .⁵⁴ The parameters obtained from the analyses of the normal-state $C_p(T)$ data are summarized in Table IV.

The electron-phonon coupling constant is estimated from Eq. (7) as $\lambda_{e-\text{ph}} = 0.443$ using $\mu^* = 0.13$, $T_c = 0.92 \text{ K}$ and $\Theta_D = 298 \text{ K}$. Then from Eq. (6) we obtain the bare Sommerfeld coefficient as $\gamma_0 = 4.46 \text{ mJ/mol K}^2$. From the value of γ_0 we estimate $\mathcal{D}(E_F) = 1.89(1) \text{ states/(eV f.u.)}$ for both spin directions from Eq. (6), which is very close to that of CaPd_2As_2 in Table IV. The Fermi velocity obtained from Eq. (9)

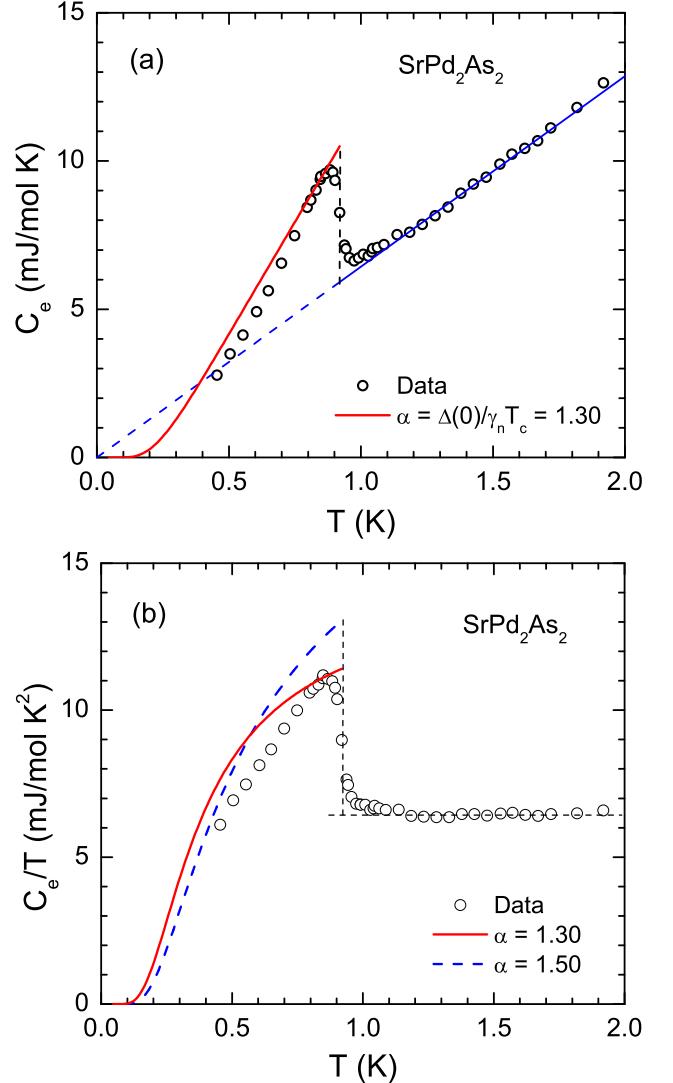


FIG. 12: (Color online) (a) The electronic contribution C_e versus temperature T at low T obtained by subtracting the phonon contribution from the measured $C_p(T)$ of SrPd_2As_2 . (b) C_e/T versus T . The solid red curves in (a) and (b) are the theoretical predictions of the α -model for $\alpha = 1.30$ and the dashed blue curve in (b) is for $\alpha = 1.50$.

is $v_F = 1.69 \times 10^8 \text{ cm/s}$, and the mean free path for this value of v_F and $\rho_0 = 4.9 \mu\Omega \text{ cm}$ using Eq. (11) is $\ell = 11.6 \text{ nm}$. The ω_p and $\lambda_L(0)$ estimated from Eqs. (14) and (16), respectively, are listed in Table VII.

The electronic contribution $C_e(T)$ to the measured low- T $C_p(T)$ of SrPd_2As_2 , obtained by subtracting $\beta T^3 + \delta T^5$ from $C_p(T)$ according to Eq. (3), is plotted versus T in Fig. 12(a), and $C_e(T)/T$ is plotted versus T in Fig. 12(b). Utilizing the entropy-conserving construction in Fig. 12(b) we obtain $\Delta C_e(T_c)/T_c = 5.0(2) \text{ mJ/mol K}^2$, $\Delta C_e(T_c) = 4.6(2) \text{ mJ/mol K}$ using $T_c = 0.92(5) \text{ K}$ and $\Delta C_e(T_c)/\gamma_n T_c = 0.77(5)$ using $\gamma_n = 6.43(3) \text{ mJ/mol K}^2$. The value of $\Delta C_e(T_c)/\gamma_n T_c$ is significantly smaller than the BCS weak-coupling value of 1.43, as was also the case

for CaPd_2As_2 discussed above, and from Eq. (19) we obtain $\alpha = 1.30(4)$ which may be compared with the BCS value of 1.764. In Figs. 12(a) and 12(b) we show as the red curves the respective theoretical predictions of the α -model obtained using $\alpha = 1.30$ in Eqs. (21). Also shown as the dashed blue curve in Fig. 12(b) is the theoretical prediction for $\alpha = 1.50$, which is the value that best fits the $H_c(T)$ data in Fig. 13(a) below.

The $H_c(T)$ for SrPd_2As_2 is obtained by integrating the $C_e(T)$ data in Fig. 12 according to Eqs. (22) and the results are shown in Fig. 13(a). The shoulder just above T_c arises from the high- T shoulder in the $C_e(T)$ data in Figs. 12(a) and 12(b). The value of $H_c(0)$ is calculated from Eq. (24) using $\alpha = 1.30$, $\gamma_n = 6.43 \text{ mJ/molK}^2$ and $T_c = 0.92 \text{ K}$, yielding $H_c(0) = 5.47 \text{ mT}$. The theoretical prediction of the α -model in Eqs. (25) for $H_c(T)$ using these parameters is plotted in Fig. 13(a). Although the T dependence of the data is reproduced, the calculated magnitude does not agree with the data. A better fit as shown in Fig. 13(a) by the blue dashed curve is obtained using $\alpha = 1.50$, for which $H_c(0)$ is calculated as above to be 6.3 mT.

The H_{c2} versus T data obtained from the above $C_p(T)$ and $\rho(T)$ measurements with $H \parallel c$ are shown in Fig. 13(b). As already mentioned the two measurements show different T_c 's in zero field. Consistent with this difference, the $H_{c2}(T)$ behavior derived from the $\rho(T)$ data indicates the presence of a surface sheath critical field H_{c3} that is larger than the bulk H_{c2} . The above values of $H_c(0)$ for both $\alpha = 1.30$ or 1.50 are much smaller than the bulk $H_{c2}(0)$ extrapolated from the heat capacity data in Fig. 13(b), indicating type-II superconductivity in SrPd_2As_2 as was also found above to be the case in CaPd_2As_2 .

From the $C_p(T)$ data in Fig. 13(b) one obtains $dH_{c2}(T)/dT|_{T=T_c} = -0.12(4) \text{ T/K}$. Equation (26) then gives $H_{c2}^{\text{Orb}}(0) = 0.077 \text{ T}$ in the clean limit and $H_{c2}^{\text{Orb}}(0) = 0.073 \text{ T}$ in the dirty limit. Using $\alpha = 1.30$, the Pauli-limiting field is obtained from Eq. (28) as $H_P(0) = 1.37 \text{ T}$ and the Maki parameter in Eq. (29) is then $\alpha_M = 0.08$. An estimate of $H_{c2}(T)$ obtained from the WHH prediction in Eqs. (30) using $\alpha_M = 0.08$ and $\lambda_{\text{so}} = 0$ is shown as the solid red curve in Fig. 13(b), from which we obtain $H_{c2}(0) = 70 \text{ mT}$.

The Ginzburg-Landau parameter is obtained from Eq. (33) using $H_{c2}(0) = 70 \text{ mT}$ and $H_c(0) = 5.5 \text{ mT}$, yielding $\kappa_{\text{GL}} = 9.0$. The lower critical field estimated from Eq. (34) is $H_{c1}(0) = 0.94 \text{ mT}$. The Ginzburg-Landau coherence length at $T = 0$ obtained from Eq. (35) is $\xi(0) = 69 \text{ nm}$ which together with $\ell = 11.6 \text{ nm}$ and Eq. (38) for the dirty limit gives $\xi_0 = 509 \text{ nm}$. The Fermi velocity estimated from ξ_0 using Eq. (41) is $v_F = 0.25 \times 10^8 \text{ cm/s}$ for $\alpha = 1.30$ which is of the same order as the above estimated value of v_F from the density of states. Corresponding values of the above parameters for $\alpha = 1.50$ were also calculated. A summary of the measured and derived superconducting parameters for SrPd_2As_2 is given in Table VII.

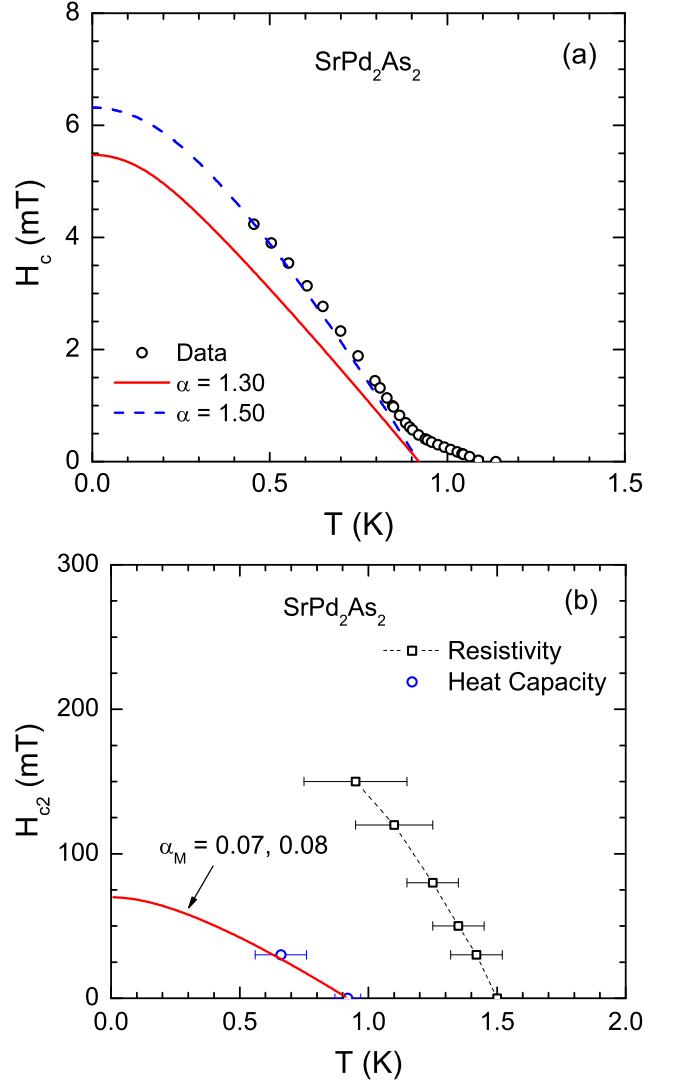


FIG. 13: (Color online) (a) Thermodynamic critical field $H_c(T)$ obtained from the free energy considerations from the zero field superconducting state $C_p(T)$ data. The solid red and dashed blue curves are the theoretical predictions of the α -model for $\alpha = 1.30$ and 1.50, respectively. (b) Upper critical field $H_{c2}(T)$ of SrPd_2As_2 determined from the electrical resistivity $\rho(T, H)$ and heat capacity $C_p(T, H)$ data in Figs. 9(b) and 10(b), respectively. The red curve is the prediction of the WHH theory in Eqs. (30) for $\alpha_M = 0.07$ and 0.08 and $\lambda_{\text{so}} = 0$.

C. Magnetization and Magnetic Susceptibility

The ZFC $\chi(T) \equiv M(T)/H$ data for a SrPd_2As_2 single crystal measured in $H = 3.0 \text{ T}$ are shown in Fig. 14 together with the intrinsic χ obtained from fitting $M(H)$ isotherm data for $H \geq 2 \text{ T}$ in the Appendix by Eq. (A.1). These two data sets are in excellent agreement over the whole T range, indicating the near absence of ferromagnetic and saturable paramagnetic impurities in the crystal. The very small upturns below $\sim 10 \text{ K}$ in $\chi(T)$ in Fig. 14 are attributed to a trace amount of paramagnetic

TABLE VII: Measured and derived superconducting and relevant normal state parameters for SrPd_2As_2 . T_c : bulk superconducting transition temperature; γ_n : observed Sommerfeld coefficient of the linear term in the low- T normal-state heat capacity; λ_{e-ph} : electron-phonon coupling constant; γ_0 : bare Sommerfeld coefficient; ℓ : mean free path at low T ; ω_p : plasma angular frequency; λ_L : London penetration depth; λ_{eff} : magnetic penetration depth; H_{c2}^{Orb} : orbital upper critical magnetic field; Δ : superconducting order parameter; $\alpha = \Delta(0)/k_B T_c$; ΔC_e : heat capacity jump at T_c ; H_P : Pauli limiting upper critical field; α_M : Maki parameter; H_c , H_{c1} , H_{c2} : thermodynamic, lower critical, and fitted upper critical magnetic fields, respectively; κ_{GL} : Ginzburg-Landau parameter; ξ : Ginzburg-Landau coherence length; ξ_0 : BCS superconducting coherence length.

| SrPd ₂ As ₂ property | value |
|--|---------------------------------|
| T_c (K) | 0.92(5) |
| γ_n (mJ/mol K ²) | 6.43(3) |
| λ_{e-ph} | 0.443 |
| γ_0 (mJ/mol K ²) | 4.46 |
| $\ell (m^* = m_e)$ (nm) | 11.6 |
| $\omega_p (m^* = m_e)$ (10 ¹⁶ rad/s) | 1.83 |
| $\lambda_L^{\text{calc}}(0)$ (clean limit) (nm) | 16.4 |
| $\lambda_{\text{eff}}^{\text{obs}}(0)$ (nm) | 170(70) |
| $H_{c2}^{\text{Orb}}(T = 0)$ (dirty limit) (T) | 0.073 |
| $\Delta(0)/k_B$ (K) (observed) | 2.05(20) |
| | $\alpha = 1.30$ $\alpha = 1.50$ |
| ΔC_e (mJ/mol K) | 4.6(2) 6.1(4) |
| $\Delta C_e/\gamma_n T_c$ | 0.77(5) 1.03(8) |
| $H_P(0)$ (T) | 1.37 1.58 |
| α_M | 0.08 0.07 |
| $H_c(T = 0)$ (mT) | 5.5 6.3 |
| $H_{c1}(T = 0)$ (mT) | 0.94 1.17 |
| $H_{c2}(T = 0)$ (mT) | 70 70 |
| κ_{GL} | 9.0 7.8 |
| $\xi(T = 0)$ (nm) | 69 69 |
| ξ_0 (nm) | 509 509 |
| $\lambda_{\text{eff}}^{\text{calc}}(0)$ (dirty limit) (nm) | 110 110 |

impurities. The χ is diamagnetic and exhibits a weak T -dependence with a strong anisotropy $\chi_{ab} > \chi_c$. The large anisotropy in χ most likely originates from anisotropy in the paramagnetic Van Vleck orbital contribution χ_{VV} in Eq. (45), although the strong temperature dependence of the anisotropy is unusual and unexpected for such a compound and for which the origin is not clear. Despite having the same crystal structure, the χ anisotropy in SrPd_2As_2 is opposite to that of CaPd_2As_2 in Fig. 8 for which we observed $\chi_{ab} < \chi_c$. This difference in the sign of the anisotropy between the two compounds is evidently again attributable to a difference in the sign of the anisotropy in the Van Vleck contributions between the two compounds.

The powder and temperature (1.8–300 K) average of the intrinsic χ obtained from the $M(H)$ isotherms in the Appendix is $\langle \chi \rangle = -3.9 \times 10^{-5}$ cm³/mol. The diamagnetic core susceptibility estimated using the atomic diamagnetic susceptibilities⁷² is $\chi_{\text{core}} = -1.93 \times$

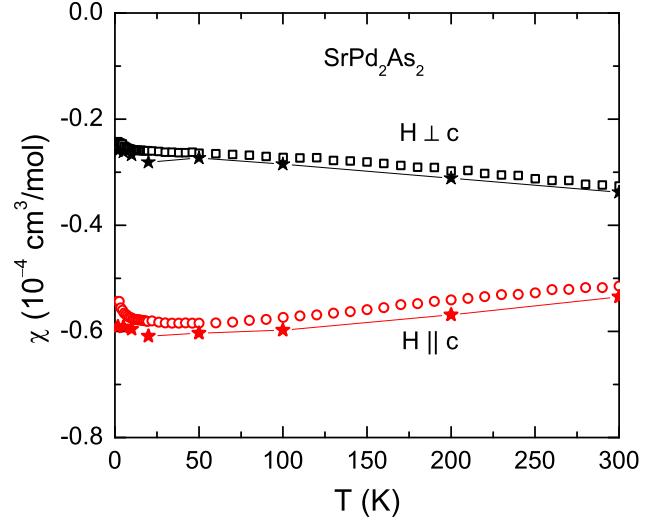


FIG. 14: (Color online) Zero-field-cooled magnetic susceptibility χ of a SrPd_2As_2 single crystal versus temperature T in a magnetic field $H = 3.0$ T applied along the c -axis (χ_c , $H \parallel c$) and in the ab -plane (χ_{ab} , $H \perp c$). The filled stars represent the intrinsic χ obtained in the Appendix from fitting $M(H)$ isotherm data by Eq. (A.1). The lines joining the stars are guides to the eye.

10^{-4} cm³/mol. The Pauli susceptibility estimated from Eq. (46) using $\mathcal{D}(E_F) = 1.89$ states/eV f.u. for both spin directions is $\chi_P = 6.1 \times 10^{-5}$ cm³/mol. The $\chi_L = -2.0 \times 10^{-5}$ cm³/mol was obtained by taking $m^* = m_e$ in Eq. (47). Then $\langle \chi_{\text{VV}} \rangle$ is obtained from these values using Eq. (45). The various χ contributions are summarized in Table VI.

VI. PHYSICAL PROPERTIES OF BaPd₂As₂ CRYSTALS

A. Electrical Resistivity

The in-plane $\rho(T)$ data for a BaPd_2As_2 crystal are shown in Fig. 15. The T dependence of ρ reveals metallic behavior with a very small residual resistivity $\rho_0 \approx 1 \mu\Omega\text{cm}$ and a large RRR ≈ 25 , demonstrating the high quality of the crystal. The scale of the resistivity for BaPd_2As_2 is smaller and the RRR is much larger than those of CaPd_2As_2 and SrPd_2As_2 . The $\rho(T)$ data were fitted by Eqs. (2) for $2 \text{ K} \leq T \leq 300 \text{ K}$ using the analytic Padé approximant function⁵⁴ as shown by red curve in Fig. 15. The excellent fit obtained yielded the fitting parameters $\rho_0 = 1.02(1) \mu\Omega\text{cm}$, $\rho(\Theta_R) = 8.84(1) \mu\Omega\text{cm}$ and $\Theta_R = 114(1) \text{ K}$. The value of the constant \mathcal{R} obtained using Eq. (2c) is $\mathcal{R} = 9.34 \mu\Omega\text{cm}$. The fit parameters are summarized in Table III.

The expanded low- T plot of $\rho(T)$ in the inset of Fig. 15 reveals an onset of superconductivity at $T_{\text{conset}} \approx 2.0$ K for $H = 0$ with zero resistance at about 0.6 K. However,

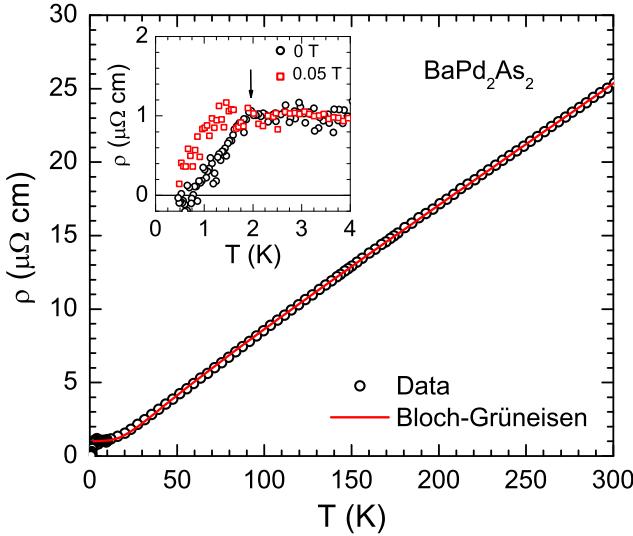


FIG. 15: (Color online) In-plane electrical resistivity ρ of a BaPd_2As_2 crystal versus temperature T measured in zero magnetic field H . The red curve is a fit by the Bloch-Grüneisen model. Inset: Expanded plot of the low- T $\rho(T)$ data showing the onset of superconductivity at $T \lesssim 2.0$ K measured at $H = 0$ and 0.05 T applied along the c -axis. We infer that this superconductivity is filamentary and not bulk.

the transition width is very large compared to those of CaPd_2As_2 and SrPd_2As_2 , and the heat capacity measurements in the following section show no evidence for superconductivity above 0.45 K. An applied field of 0.05 T decreases T_{conset} by ≈ 0.8 K, as shown.

B. Heat Capacity

The $C_p(T)$ data for BaPd_2As_2 are shown in Fig. 16. Like the other two compounds, the $C_p(T = 300$ K) = 124 J/mol K is close to the expected high- T classical Dulong-Petit value. An expanded low- T plot of C_p/T versus T^2 is shown in the inset of Fig. 16. A fit of the data with $0.45 \leq T \leq 5$ K by Eq. (3) yields $\gamma_n = 4.79(2)$ mJ/mol K 2 , $\beta = 0.638(5)$ mJ/mol K 4 and $\delta = 4.0(3)$ μ J/mol K 6 , as shown by the red curve in the inset. A $\mathcal{D}(E_F) = 2.03(1)$ states/(eV f.u.) for both spin directions is estimated from γ_n by setting $\lambda_{\text{e-ph}} = 0$ in Eq. (6). A value $\Theta_D = 248(1)$ K is obtained from β using Eq. (4).

A value $\Theta_D = 227(2)$ K is obtained by fitting the $C_p(T)$ data by Eqs. (5) over the entire T range (2–300 K), as shown by the red curve in Fig. 16. Here again we used analytic Padé approximant function⁵⁴ for $C_{\text{VDebye}}(T)$ and set γ_n to the fixed value obtained above from the fit to the low- T $C_p(T)$ data. The normal-state parameters obtained from these fits are summarized in Table IV.

In contrast to the observation of the onset of superconductivity in the $\rho(T)$ data at ≈ 2.0 K in the inset of Fig. 15, no corresponding feature is observed in the

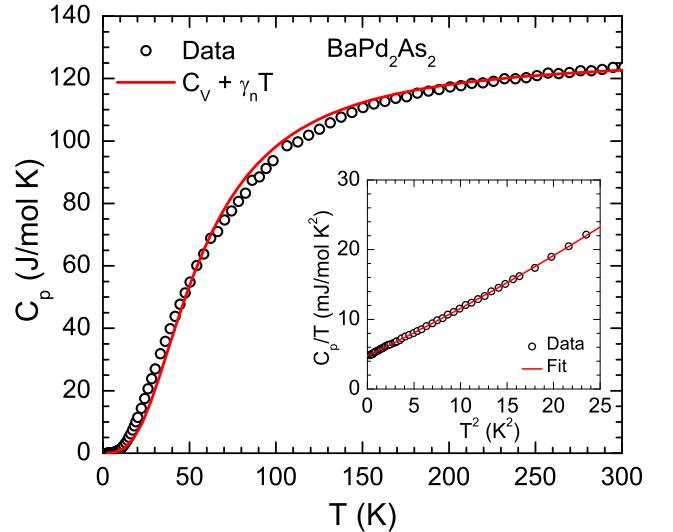


FIG. 16: (Color online) Heat capacity C_p of a BaPd_2As_2 single crystal versus temperature T for $2.4 \leq T \leq 300$ K measured in zero magnetic field. The red solid curve is the fitted sum of the contributions from the Debye lattice heat capacity $C_{\text{VDebye}}(T)$ and predetermined electronic heat capacity $\gamma_n T$ according to Eq. (5a). Inset: C_p/T versus T^2 for $0.45 \leq T \leq 5$ K. The red curve is a fit of the data by Eq. (3) for $0.45 \leq T \leq 5$ K.

bulk $C_p(T)$ data above 0.45 K in the inset of Fig. 16, which indicates that there is no bulk superconductivity in BaPd_2As_2 and hence the superconductivity detected by the $\rho(T)$ measurements is filamentary in nature.

C. Magnetization and Magnetic Susceptibility

The anisotropic $\chi(T) \equiv M(T)/H$ data of a BaPd_2As_2 single crystal in $H = 3.0$ T are shown in Fig. 17. The χ is diamagnetic over the whole T range and exhibits a weak T -dependence. We find that $\chi_c > \chi_{ab}$, which has the same sign of the χ anisotropy as in CaPd_2As_2 but is opposite to that of SrPd_2As_2 . One must keep in mind in making these comparisons that the crystal structure of BaPd_2As_2 is different from that of CaPd_2As_2 and SrPd_2As_2 . The intrinsic anisotropic susceptibilities obtained from the slopes of high-field linear fits to the $M(H)$ isotherms in the Appendix are shown by solid stars in Fig. 17. These data are in rather good agreement with the $\chi(T) \equiv M(T)/H$ data in Fig. 17 above 25 K, and indicate that the low- T upturns below 25 K are due to a small amount of paramagnetic impurities.

The different contributions to the intrinsic χ of BaPd_2As_2 were estimated following the same approach as for the Ca and Sr members above. The powder- and temperature-average of the intrinsic χ obtained from the analyses of the $M(H)$ isotherms from 1.8 to 300 K in the Appendix is $\langle \chi \rangle = -1.24 \times 10^{-4}$ cm 3 /mol. We also obtain $\chi_{\text{core}} = -2.16 \times 10^{-4}$ cm 3 /mol, $\chi_{\text{P}} = 6.6 \times 10^{-5}$ cm 3 /mol,

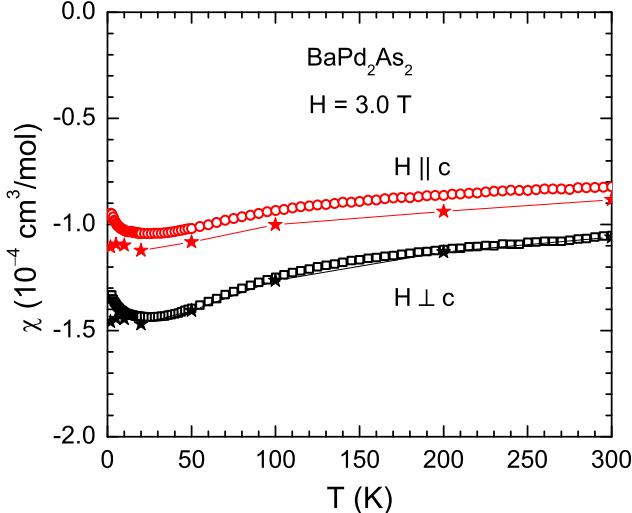


FIG. 17: (Color online) Zero-field-cooled magnetic susceptibility χ of a BaPd_2As_2 single crystal as a function of temperature T in the temperature range 1.8–300 K measured in a magnetic field $H = 3.0$ T applied along the c axis (χ_c , $H \parallel c$) and in the ab plane (χ_{ab} , $H \perp c$). The filled stars are the intrinsic χ obtained in the Appendix from fitting $M(H)$ isotherm data by Eq. (A.1). The lines joining the stars are guides to the eye.

and $\chi_L = -2.2 \times 10^{-5} \text{ cm}^3/\text{mol}$ [using $m^* = m_e$ in Eq. (47)]. A value $\langle \chi_{VV} \rangle = 4.8 \times 10^{-5} \text{ cm}^3/\text{mol}$ is then obtained using Eq. (45). These contributions are summarized in Table VI.

VII. MAGNETIC PENETRATION DEPTH MEASUREMENTS OF CaPd_2As_2 AND SrPd_2As_2

Figure 18 shows the temperature variation of the ab -plane magnetic penetration depth, $\Delta\lambda_{\text{eff}}(T) \equiv \lambda_{\text{eff}}(T) - \lambda_{\text{eff}}(0)$, measured in CaPd_2As_2 and SrPd_2As_2 crystals, represented by open circles and triangles, respectively. The absolute value of the penetration depth was obtained using the TDR technique by matching the frequency shift, $\Delta f(T)$, to the skin depth, δ , calculated from the resistivity. The superconducting transition temperature was determined as the temperature of the maximum of $d\Delta\lambda_{\text{eff}}/dT$. The determined T_c 's are 1.34 K and 1.26 K for CaPd_2As_2 and SrPd_2As_2 , respectively. These values are higher than the bulk T_c 's of 1.27(3) K and 0.92(5) K determined from respective $C_p(T)$ data (Tables V and VII, respectively). Even so, the actual onset of the diamagnetic response is observed at even higher temperatures, $T_c^{\text{onset}} = 1.50$ K and 1.72 K for CaPd_2As_2 and SrPd_2As_2 , respectively. The T dependences of $\Delta\lambda_{\text{eff}}$ for the two compounds up to T_c are shown in the inset of Fig. 18.

At low temperatures, the $\Delta\lambda_{\text{eff}}(T)$ in Fig. 18 of each sample shows a clear saturation on cooling, which is an indication of a fully-gapped superconducting order pa-

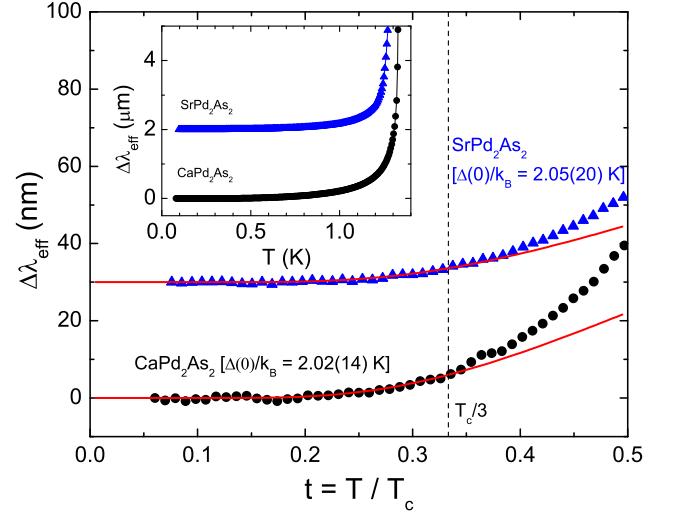


FIG. 18: The change $\Delta\lambda_{\text{eff}} \equiv \lambda_{\text{eff}}(T) - \lambda_{\text{eff}}(T \rightarrow 0)$ of the magnetic penetration depth λ_{eff} measured in CaPd_2As_2 (filled circles) and SrPd_2As_2 (filled triangles). The data for SrPd_2As_2 are shifted vertically upwards by 30 nm for clarity. The solid curve for each compound is the best fit of the data by the prediction in Eq. (49) for a single-gap s -wave BCS superconductor for $T \lesssim T_c/3$. The vertical dashed line is the upper temperature limit for the fits. Inset: $\Delta\lambda_{\text{eff}}(T)$ for both compounds up to $T = T_c$. The data for SrPd_2As_2 are all shifted upwards by 2 μm for clarity.

rameter in both compounds. Our compounds are dirty-limit superconductors, for which the magnetic penetration depth in the single-band model for $T/T_c \ll 1$ in Tinkham's notation⁵⁸ is

$$\lambda_{\text{eff}}(T) = \lambda_L(T) \sqrt{1 + \frac{\xi_0}{\ell}}, \quad (48a)$$

where $\lambda_L(T)$ is the clean-limit BCS London penetration depth prediction, yielding the $T = 0$ expression in Eq. (37), and

$$\frac{\lambda_{\text{eff}}(T)}{\lambda_{\text{eff}}(0)} = \frac{\lambda_L(T)}{\lambda_L(0)}. \quad (48b)$$

Defining $\Delta\lambda(T) = \lambda(T) - \lambda(0)$, one obtains

$$\frac{\Delta\lambda_{\text{eff}}(T)}{\lambda_{\text{eff}}(0)} = \frac{\Delta\lambda_L(T)}{\lambda_L(0)}. \quad (48c)$$

The right-hand side of this equation is just the clean-limit BCS prediction for local electrodynamics given by^{46,49,60}

$$\frac{\Delta\lambda_L(T)}{\lambda_L(0)} = \sqrt{\frac{\pi\Delta(0)}{2k_B T}} \exp\left[-\frac{\Delta(0)}{k_B T}\right]. \quad (49)$$

Combining Eqs. (48c) and (49) gives

$$\Delta\lambda_{\text{eff}}(T) = \lambda_{\text{eff}}(0) \sqrt{\frac{\pi\Delta(0)}{2k_B T}} \exp\left[-\frac{\Delta(0)}{k_B T}\right]. \quad (50)$$

The experimental data are fitted well up to $T \approx T_c/3$ by Eq. (50) as shown by the solid curves in Fig. 18, where the fitting parameters are $\lambda_{\text{eff}}(0) = 210 \pm 60$ nm and $\Delta(0)/k_B = 2.02 \pm 0.14$ K for CaPd_2As_2 and $\lambda_{\text{eff}}(0) = 170 \pm 70$ nm and $\Delta(0)/k_B = 2.05 \pm 0.20$ K for SrPd_2As_2 . The listed errors are systematic errors obtained from the spread of the fitting parameters depending on different choices of the upper temperature limit near $T_c/3$.

Using the bulk T_c values in Tables V and VII and the above values of $\Delta(0)/k_B$, we obtain $\alpha = 1.59(14)$ for CaPd_2As_2 and $\alpha = 2.23(0.32)$ for SrPd_2As_2 . The value of α for CaPd_2As_2 is identical within the error bars to the value of 1.58(2) in Eq. (20) that was determined from the heat capacity jump, both of which are smaller than the value $\alpha_{\text{BCS}} \approx 1.764$ expected for an isotropic weak-coupling BCS superconductor.^{46,60} This reduction is most likely due to a moderate anisotropy of the order parameter⁴⁶ rather than multiple order parameters, because well-known multi-gap superconductors such as MgB_2 ,⁷⁵ NbSe_2 ,⁷⁶ and LiFeAs (Ref. 77) have shown much lower values of α for the smaller gap. The accuracy of α for SrPd_2As_2 that we could write down is uncertain because of the significantly larger superconducting transition width obtained from the heat capacity measurements for this compound, and will therefore not be further considered.

The above parameter values obtained for CaPd_2As_2 and SrPd_2As_2 are listed in Tables V and VII, respectively.

VIII. SUMMARY AND CONCLUSIONS

The crystallographic, electronic transport, thermal, magnetic and superconducting properties of APd_2As_2 ($A = \text{Ca, Sr, Ba}$) single crystals were investigated. The magnetic measurements in the normal state reveal anisotropic diamagnetism with $\chi_c > \chi_{ab}$ for CaPd_2As_2 and BaPd_2As_2 , and $\chi_{ab} > \chi_c$ for SrPd_2As_2 . The $\chi(T)$, $\rho(T)$ and $C_p(T)$ data indicate *sp*-band metal behavior of all three compounds and provide conclusive evidence for bulk superconductivity in CaPd_2As_2 and SrPd_2As_2 but only filamentary superconductivity in BaPd_2As_2 which has a different crystal structure. The superconducting transition temperatures as estimated from the zero-field $C_p(T)$ data are $T_c = 1.27(3)$ K for CaPd_2As_2 and $T_c = 0.92(5)$ K for SrPd_2As_2 . The heat capacity jump at T_c , $\Delta C_e(T_c)$, of CaPd_2As_2 in $H = 0$ is extremely sharp, which allows unambiguous analyses of the derived electronic contribution $C_e(T)$ in the superconducting state. The $\Delta C_e(T_c)/\gamma_n T_c = 1.14(3)$ is significantly smaller than the BCS prediction of 1.43. We analyzed the $C_e(T)$ data in the superconducting state using the α -model,^{46,61} where $\alpha = \Delta(0)/k_B T_c$. A good fit to the data was obtained using $\alpha = 1.58$, which is significantly smaller than the BCS value of 1.764 which we surmise is due to anisotropy in the superconducting *s*-wave gap. The $H_c(T)$ is also in agreement with the α -model predic-

TABLE VIII: Parameters obtained from fitting $M(H)$ isotherms of APd_2As_2 ($A = \text{Ba, Ca, Sr}$) at 1.8 K by Eqs. (A.1) and (A.2), where $\theta_{\text{imp}} \equiv 0$ and $S_{\text{imp}} \equiv 2$. Here M_s is the saturation magnetization of ferromagnetic impurities, χ is the intrinsic susceptibility, and f_{imp} is the molar fraction of the paramagnetic impurities.

| Compound | field direction | M_s ($\frac{\text{G cm}^3}{\text{mol}}$) | χ ($10^{-5} \frac{\text{cm}^3}{\text{mol}}$) | f_{imp} (10^{-4}) |
|----------------------------|-----------------|--|---|--------------------------------|
| CaPd_2As_2 | $H \perp c$ | 0.06(7) | -15.38(5) | 1.01(2) |
| | $H \parallel c$ | 0.48(3) | -14.20(3) | 0.86(1) |
| SrPd_2As_2 | $H \perp c$ | 0.002(4) | -2.60(2) | |
| | $H \parallel c$ | 0.02(1) | -5.91(2) | |
| BaPd_2As_2 | $H \perp c$ | 0.18(3) | -14.59(4) | |
| | $H \parallel c$ | 0.20(4) | -11.07(3) | |

tion using the same value of α .

While the $\rho(T)$ data of CaPd_2As_2 exhibit a T_c consistent with that obtained from the $C_p(T)$ data, the $\rho(T)$ data of SrPd_2As_2 exhibit a higher T_c most likely due to surface sheath superconductivity. Our analysis of the normal and superconducting state $\rho(T, H)$ and $C_p(T, H)$ data of these two compounds and estimated superconducting parameters indicate type-II superconductivity with small thermodynamic critical fields and upper critical fields that are much smaller than those of the doped-FeAs based superconductors.

Acknowledgments

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Appendix: Presentation and Analysis of $M(H)$ Isotherms

1. CaPd_2As_2

The $M(H)$ isotherms for a CaPd_2As_2 crystal measured at eight temperatures between 1.8 and 300 K for H applied both along the *c*-axis (M_c , $H \parallel c$) and in the *ab*-plane (M_{ab} , $H \perp c$) are shown in Fig. 19. Consistent with the χ , the M is diamagnetic (negative) and exhibits weak anisotropy with $M_c(H) > M_{ab}(H)$. For $T \geq 50$ K the $M(H)$ curves are almost linear in H , however at low- T a slight nonlinearity is observed that can be attributed to the presence of a small amount of saturable paramagnetic (PM) impurities. Further, the presence of trace amount of ferromagnetic (FM) impurities is also inferred from the $M(H)$ curves.

We estimated the FM impurity contribution by fitting

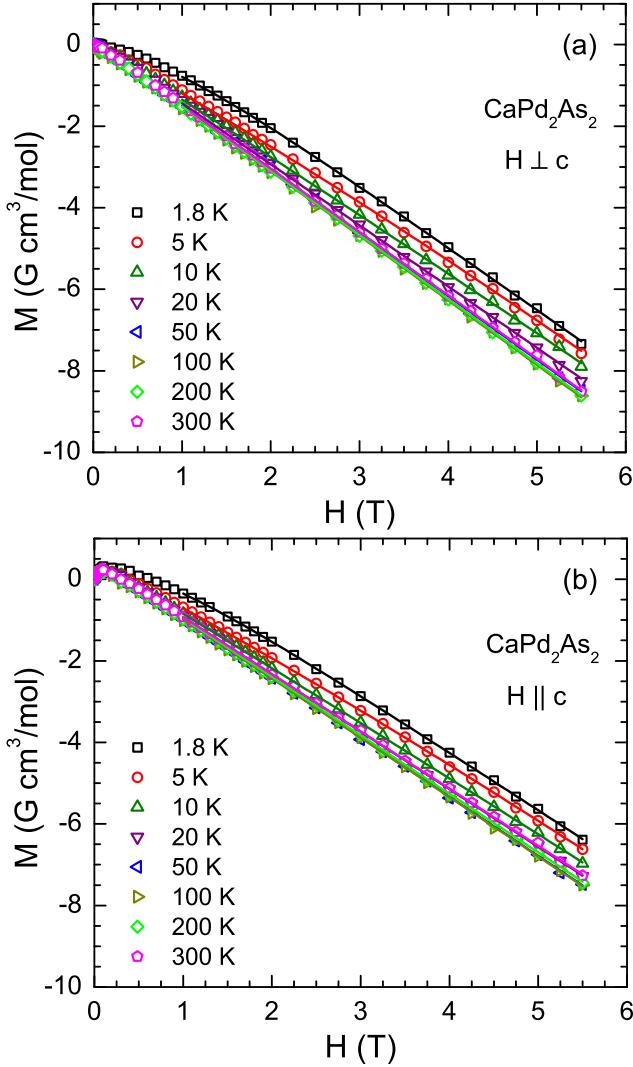


FIG. 19: (Color online) Isothermal magnetization M of CaPd_2As_2 versus applied magnetic field H at different temperatures, as listed, for magnetic fields applied (a) in the ab -plane ($H \perp c$) and, (b) along the c -axis ($H \parallel c$). The solid curves are fits of the $M(H)$ data by Eqs. (A.2) for $1.0 \leq H \leq 5.5$ T.

the $M(H)$ data for $T \geq 50$ K and $H \geq 2$ T by

$$M(H) = M_s + \chi H, \quad (\text{A.1})$$

where M_s is the FM impurity saturation magnetization. For $T \geq 50$ K the M_s is found to be almost T -independent and anisotropic with values for $H \parallel c$ and $H \perp c$ listed in Table VIII. The M_s value of $0.48 \text{ G cm}^3/\text{mol}$ for $H \parallel c$ is equivalent to the saturation magnetization of 39 molar ppm of Fe metal impurities suggesting that the only trace amounts of FM impurities are present in the crystal. However due to the small magnitude of the diamagnetic χ even trace amounts of FM impurities are observable in χ and M measurements.

Once the FM impurity contributions M_s to the magnetizations were determined, we analyzed the low- T $M(H)$

data for both field directions by

$$M(T, H) = M_s + \chi H + f_{\text{imp}} M_{s_{\text{imp}}} B_{S_{\text{imp}}}(x). \quad (\text{A.2a})$$

Here χ is the intrinsic susceptibility of the compound, f_{imp} is the molar fraction of PM impurities, $M_{s_{\text{imp}}} = N_A g_{\text{imp}} \mu_B S_{\text{imp}}$ is the PM impurity saturation magnetization, N_A is Avogadro's number, μ_B is the Bohr magneton, and g_{imp} and S_{imp} are the spectroscopic splitting factor (g -factor) and the spin of the impurities, respectively. Our unconventional definition of the Brillouin function $B_{S_{\text{imp}}}$ is⁷⁸

$$B_{S_{\text{imp}}}(x) = \frac{1}{2S_{\text{imp}}} \left\{ (2S_{\text{imp}} + 1) \coth \left[(2S_{\text{imp}} + 1) \frac{x}{2} \right] - \coth \left(\frac{x}{2} \right) \right\}, \quad (\text{A.2b})$$

where

$$x \equiv \frac{g_{\text{imp}} \mu_B H}{k_B(T - \theta_{\text{imp}})}. \quad (\text{A.2c})$$

A Weiss temperature θ_{imp} is included in the argument of $B_{S_{\text{imp}}}(x)$ to take into account for interactions between the paramagnetic impurities in an average mean-field way.

While fitting the $M(H)$ data the impurity g -factor was set to $g_{\text{imp}} = 2$ and the M_s values for $H \perp c$ and $H \parallel c$ were set to the values listed in Table VIII. The $M(H)$ data for both H directions were fitted for magnetic fields in the range $1.0 \leq H \leq 5.5$ T. The S_{imp} values for both H directions were found to be $S_{\text{imp}} = 2.0(2)$; therefore, in the final fits we set $S_{\text{imp}} = 2$. The θ_{imp} values for both field directions were found to be close to zero and therefore in the final fits we set $\theta_{\text{imp}} \equiv 0$. The solid curves in Fig. 19 show the final fits of the $M(H)$ data by Eqs. (A.2). The parameters obtained from the fits of the $M(H)$ isotherms at $T = 1.8$ K are listed in Table VIII. The intrinsic χ values obtained from the fits of the $M(H)$ data at different temperatures are shown by stars in Fig. 8. The T dependence of the intrinsic χ values clearly indicates that the low- T upturns in the measured $\chi(T) \equiv M(T)/H$ data are extrinsic.

2. SrPd_2As_2

The isothermal $M(H)$ data for a SrPd_2As_2 crystal at different T are shown in Fig. 20. Similar to the $\chi(T) \equiv M(T)/H$ data in Fig. 14, the $M(H)$ data exhibit anisotropic diamagnetic behavior with $M_{ab}(H) > M_c(H)$. In order to obtain the contributions from the FM impurities the $M(H)$ data for $H \geq 2$ T at $T \geq 1.8$ K were fitted by Eq. (A.1) which gave the average M_s values of $0.002(4)$ for $H \perp c$ and $0.02(1)$ for $H \parallel c$. The fitting parameters for both $H \parallel c$ and $H \perp c$ for $T = 1.8$ K are listed in Table VIII. The intrinsic susceptibilities obtained from the analysis of $M(H)$ data by Eq. (A.1)

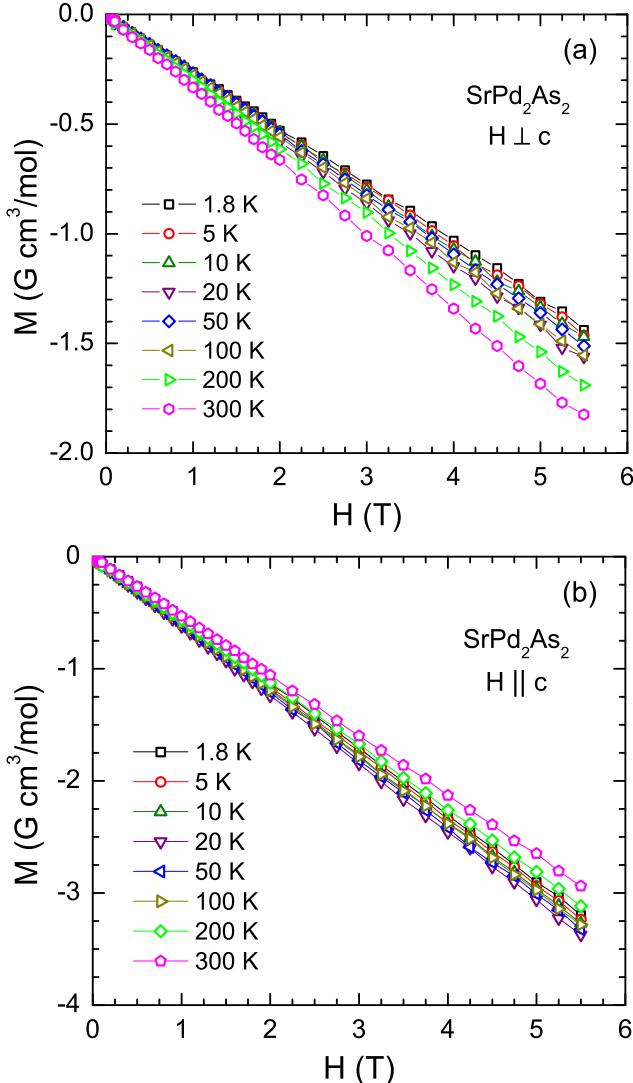


FIG. 20: (Color online) Isothermal magnetization M of SrPd_2As_2 versus magnetic field H at different temperatures as in Fig. 19.

are shown by stars in Fig. 14. The paramagnetic impurity concentration is zero within our resolution, since no curvature in the $M(H)$ curves on cooling to low T in addition to that due to the FM impurities was detected.

3. BaPd_2As_2

The $M(H)$ isotherms for a BaPd_2As_2 crystal at different T are shown in Fig. 21. The $M(H)$ curves exhibit weakly anisotropic diamagnetic behavior with $M_c(H) > M_{ab}(H)$. The intrinsic χ was obtained by fitting the $M(H)$ isotherms at each T by Eq. (A.1) for $H \geq 2$ T which yielded a temperature-averaged (for $T \geq 50$ K) FM saturation values $M_s^{ab} = 0.18(3) \text{ G cm}^3/\text{mol}$ and $M_s^c = 0.20(4) \text{ G cm}^3/\text{mol}$ which are equivalent to the magnetization contributions from 12 and 16 molar ppm of Fe

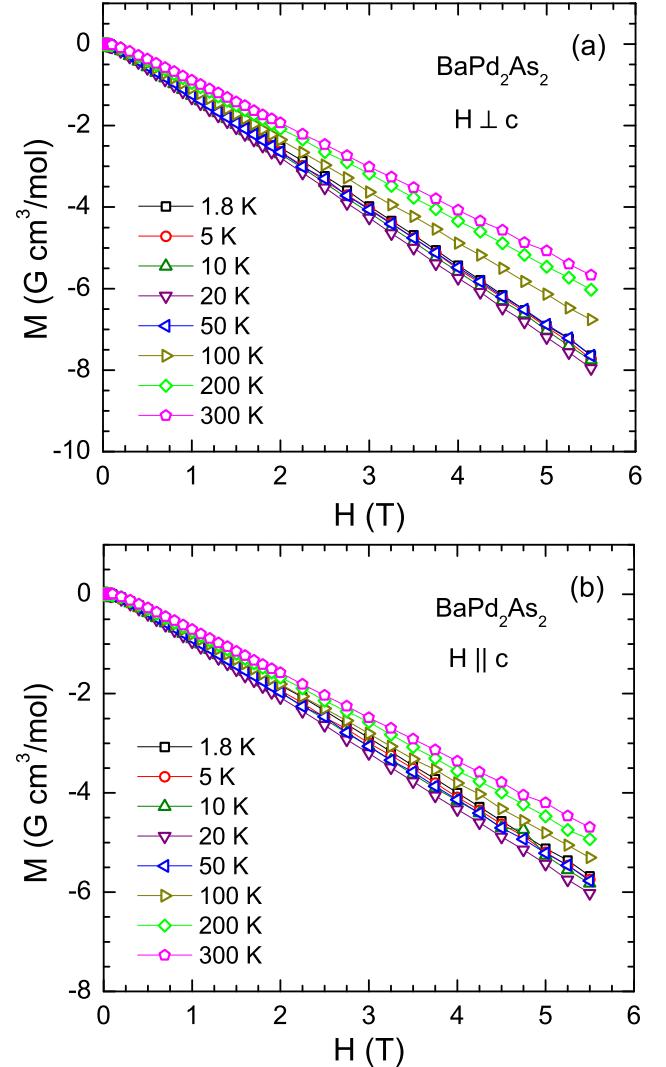


FIG. 21: (Color online) Isothermal magnetization $M(H)$ of BaPd_2As_2 versus magnetic field measured at different temperatures as in Fig. 19.

metal impurities, respectively. As in the Sr compound, the paramagnetic impurity concentration is zero within our resolution, since no curvature in the $M(H)$ curves on cooling to low T in addition to that due to the FM impurities was detected.

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